XC6504 Series

ETR0347-006

0.6μA Ultra Low Power Consumption Small Voltage Regulator (C_L Capacitor-Less)

■ GENERAL DESCRIPTION

The XC6504 series is a highly accurate CMOS voltage regulator that achieves very low supply current operation of 0.6μA. Even output current is 1μA (when light load), the XC6504 can provide high accurate outputs, which is ideally suited for the applications to draw less output current. The usage of super small package USPN-4B02 (0.75 x 0.95mm) and the advantage of capacitor-less stable operation can contribute the board space saving outstandingly. The IC consists of a reference voltage source, an error amplifier, a driver transistor, over-current protection circuit, and a phase compensation circuit.

The device is compatible with a low ESR ceramic output capacitor C_L. Moreover, the device can provide stable output even without a C_L output capacitor because of the excellent internal phase compensation.

Output voltage is fixed internally by laser trimming technology and can be selectable in 0.1V increments within the range of 1.1V to 5.0V. The CE function enables the device to be put into standby mode by inputting a low level signal to the CE pin thereby reducing current consumption to less than 0.1μA. In the standby mode, if a C_L output capacitor is used, the electric charge stored at C_L can be discharged via the internal switch and as a result, the V_{OUT} pin quickly returns to the V_{SS} level.

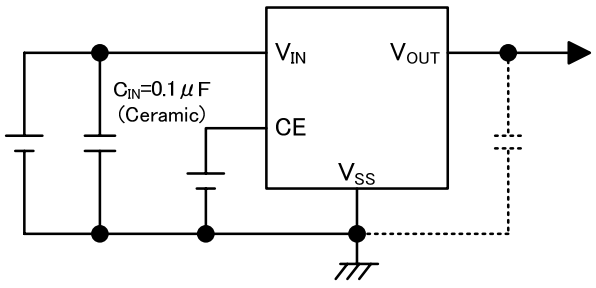
■ APPLICATIONS

- Mobile devices / terminals
- Wireless LAN
- Modules (wireless, cameras, etc.)

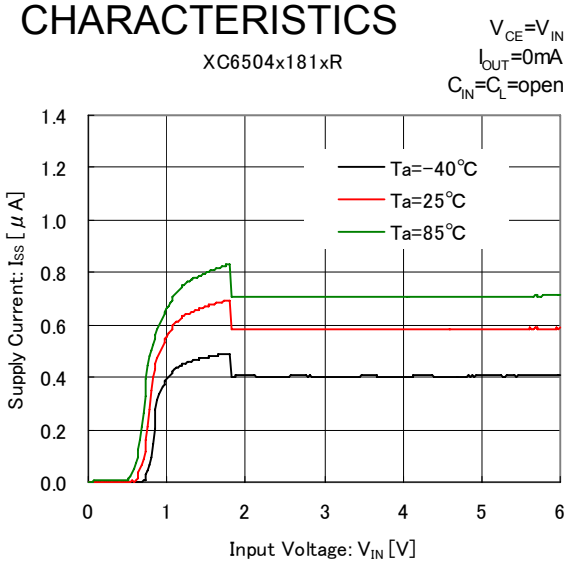
■ FEATURES

Supply Current	:	0.6μA
Input Voltage Range	:	1.4V～6.0V
Output Voltage Range	:	1.1V～5.0V (0.1V increments)
Output Accuracy	:	±0.02V@V_{OUT}＜2.0V ±1%@V_{OUT}≧2.0V
Temperature Stability	:	±50ppm/℃
Maximum Output Current	:	150mA
Low On Resistance	:	3.3Ω@V_{OUT}=3.0V
Standby Current	:	0.01μA
Protection Current	:	Current Limiter Shot Circuit Protection
CE Function	:	C_L Auto Discharge ON/OFF Logic=Enable High
Output Capacitor	:	Low ESR Ceramic Capacitor (C_L Capacitor-Less Compatible)
Operating Ambient Temperature	:	-40℃～+85℃
Packages	:	USPN-4B02 SSOT-24 SOT-25 USPQ-4B04
Environmentally Friendly	:	EU RoHS Compliant, Pb Free

■ TYPICAL APPLICATION CIRCUIT

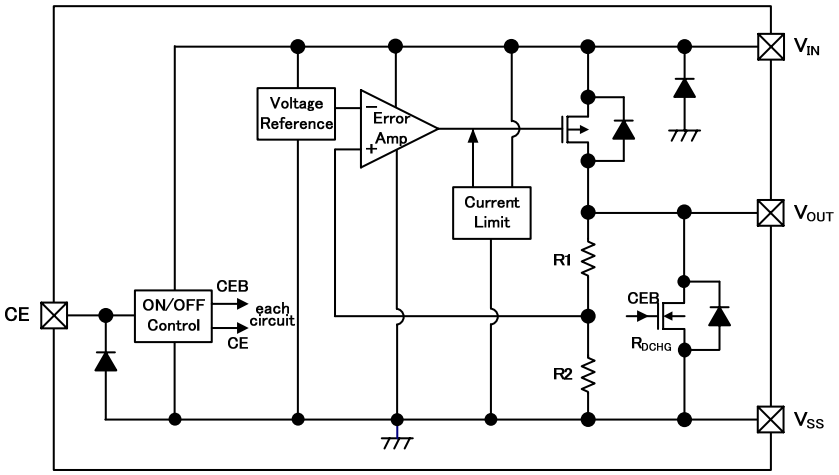


■ TYPICAL PERFORMANCE CHARACTERISTICS



■BLOCK DIAGRAM

XC6504 Series, Type A



* Diodes inside the circuits are ESD protection diodes and parasitic diodes.

■PRODUCT CLASSIFICATION

●Ordering Information

XC6504①②③④⑤⑥−⑦

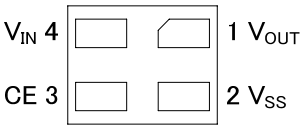
DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Type	A	Refer to Selection Guide
②③	Output Voltage	11~50	e.g. 1.8V → ②=1, ③=8
④	Output Voltage Accuracy	1	±0.02V (V_{OUT}＜2.0V), ±1% (V_{OUT}≧2.0V)
⑤⑥−⑦(*1)	Packages (Order Unit)	7R-G	USPN-4B02 (5,000/Reel)
		NR-G	SSOT-24 (3,000/Reel)
		MR-G	SOT-25 (3,000/Reel)
		9R-G	USPQ-4B04 (3,000/Reel)

(*1) The “-G” suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.

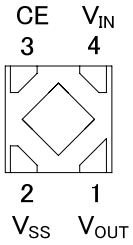
●Selection Guide

TYPE	CURRENT LIMITTER	CE PULL-DOWN RESISTOR	C_L AUTO-DISCHARGE
A	Yes	No	Yes

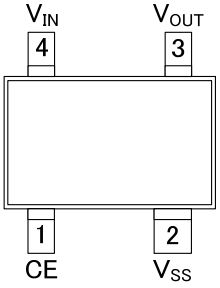
■PIN CONFIGURATION



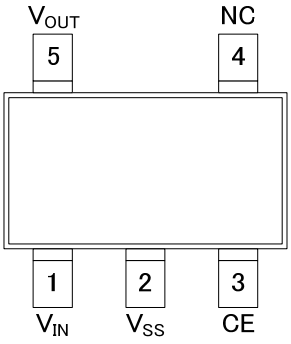
USPN-4B02
(BOTTOM VIEW)



USPQ-4B04
(BOTTOM VIEW)



SSOT-24
(TOP VIEW)



SOT-25
(TOP VIEW)

*The dissipation pad for the USPQ-4B04 package should be solder-plated in reference mount pattern and metal masking so as to enhance mounting strength and heat release.
If the pad needs to be connected to other pins, it should be connected to the V_{SS} (No. 2) pin.

■PIN ASSIGNMENT

PIN NUMBER				PIN NAME	FUNCTIONS
USPN-4B02	USPQ-4B04	SSOT-24	SOT-25		
1	1	3	5	V_{OUT}	Output
2	2	2	2	V_{SS}	Ground
3	3	1	3	CE	ON/OFF Control
4	4	4	1	V_{IN}	Power Supply Input
-	-	-	4	NC	No Connection

■FUNCTION CHART

PIN NAME	SIGNAL	STATUS
CE	L	Stand-by
	H	Active
	OPEN	Unstable

* Please avoid the state of OPEN, and connect CE pin to any arbitrary voltage.

■ABSOLUTE MAXIMUM RATINGS

Ta=25℃

PARAMETER		SYMBOL	RATINGS	UNITS
Input Voltage		V_{IN}	-0.3～+6.5	V
Output Current		I_{OUT}	470 (*1)	mA
Output Voltage		V_{OUT}	-0.3～V_{IN}+0.3 or +6.5 (*2)	V
CE Input Voltage		V_{CE}	-0.3～+6.5	V
Power Dissipation	USPQ-4B04	Pd	100	mW
			550 (PCB mounted) (*3)	
	USPN-4B02		100	
			550 (PCB mounted) (*3)	
	SSOT-24		150	
			500 (PCB mounted) (*3)	
	SOT-25		250	
			600 (PCB mounted) (*3)	
Operating Ambient Temperature		Topr	-40～+85	℃
Storage Temperature		Tstg	-55～+125	℃

All voltages are described based on the V_{SS}.

(*1) Please use within the range of $I_{OUT} \leqq Pd / (V_{IN}-V_{OUT})$

(*2) The maximum rating corresponds to the lowest value between V_{IN}+0.3 or +6.5.

(*3) This is a reference data taken by using the test board. Please refer to page 25～28 for details.

■ELECTRICAL CHARACTERISTICS

Ta=25℃

PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNITS	CIRCUIT
Input Voltage	V_{IN}	I_{OUT}=1μA		1.4	-	6.0	V	①
Output Voltage	$V_{OUT(E)}$ (*1)	$V_{OUT(T)}$＜2.0V		-0.02	$V_{OUT(T)}$ (*2)	+0.02	V	①
		$V_{OUT(T)}$≧2.0V		×0.99		×1.01		
Maximum Output Current	I_{OUTMAX}			150	-	-	mA	①
Load Regulation	ΔV_{OUT}	1μA≦I_{OUT}≦1mA		-	3	16	mV	①
		1mA≦I_{OUT}≦150mA		-	17	50		
Dropout Voltage	Vdif1 (*3)	I_{OUT}=50mA		-	E-1 (*4)		V	①
	Vdif2 (*3)	I_{OUT}=150mA		-	E-2 (*4)			
Supply Current	I_{SS}	I_{OUT}=0mA	$V_{OUT(T)}$＜1.9V	-	0.60	1.27	μA	②
			1.9V≦$V_{OUT(T)}$＜4.0V	-	0.65	1.50		
			$V_{OUT(T)}$≧4.0V	-	0.80	1.80		
Stand-by Current	I_{STB}	V_{IN}=6.0V, V_{CE}=V_{SS}		-	0.01	0.10	μA	②
Line Regulation	ΔV_{OUT}/ (ΔV_{IN}・V_{OUT})	I_{OUT}=1μA	$V_{OUT(T)}$+0.5V≦V_{IN}≦6.0V	-	0.01	0.13	%/V	①
		I_{OUT}=1mA	$V_{OUT(T)}$＜1.2V, 1.7V≦V_{IN}≦6.0V	-	0.01	0.19		
			$V_{OUT(T)}$≧1.2V, $V_{OUT(T)}$+0.5V≦V_{IN}≦6.0V					
Output Voltage Temperature Characteristics	ΔV_{OUT}/ (ΔTopr ・V_{OUT})	I_{OUT}=10mA, -40℃≦Topr≦85℃		-	±50	-	ppm/℃	①
Current Limit	I_{LIM}	V_{OUT}=$V_{OUT(E)}$×0.95		150	270	-	mA	①
Short-Circuit Current	I_{SHORT}	V_{OUT}=V_{SS}		-	80	-	mA	①
C_L Auto-Discharge Resistance	R_{DCHG}	V_{CE}=V_{SS}, V_{OUT}=$V_{OUT(T)}$		280	450	640	Ω	①
CE "H" Level Voltage	V_{CEH}			0.91	-	6.00	V	③
CE "L" Level Voltage	V_{CEL}			V_{SS}	-	0.38	V	③
CE "H" Level Current	I_{CEH}	V_{IN}= 6.0V		-0.1	-	0.1	μA	③
CE "L" Level Current	I_{CEL}	V_{IN}=6.0V, V_{CE}=V_{SS}		-0.1	-	0.1	μA	③

NOTE:
Unless otherwise stated, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below:
$V_{OUT(T)}$＜2.5V : V_{IN}=3.5V
$V_{OUT(T)}$≧2.5V : V_{IN}=$V_{OUT(T)}$+1.0V
(*1) $V_{OUT(E)}$ is Effective output voltage
(*2) $V_{OUT(T)}$ is Nominal output voltage
(*3) Vdif={V_{IN1}−V_{OUT1}}
V_{IN1} is the input voltage when V_{OUT1} appears at the V_{OUT} pin while input voltage is gradually decreased.
V_{OUT1} is the voltage equal to 98% of the normal output voltage when amply stabilized $V_{OUT(T)}$+1.0V is input at the V_{IN} pin.
(*4) E-1 / E-2: DROPOUT VOLTAGE (Refer to the Voltage Chart)

■ELECTRICAL CHARACTERISTICS (Continued)

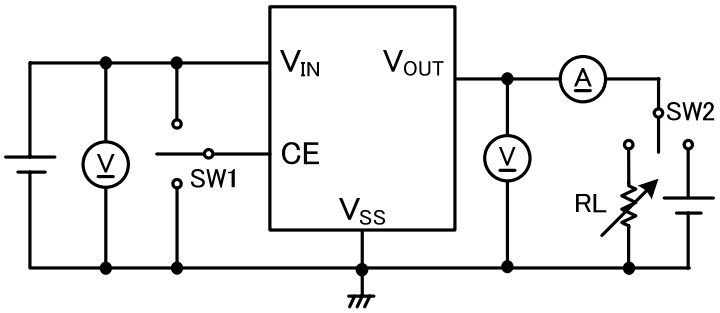
Voltage Chart

Ta=25℃

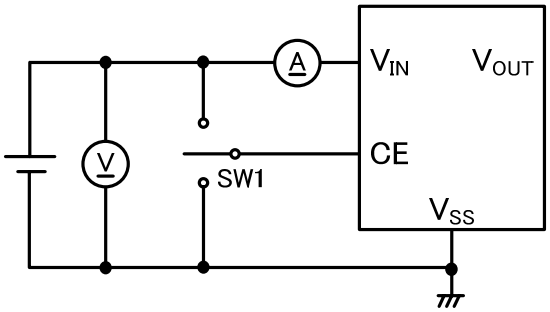
NOMINAL OUTPUT VOLTAGE	-		E-1		E-2	
	OUTPUT VOLTAGE (V)		DROPOUT VOLTAGE (V)			
$V_{OUT(T)}$ (V)	$V_{OUT(E)}$		Vdif1		Vdif2	
	MIN.	MAX.	TYP.	MAX.	TYP.	MAX.
1.1	1.0800	1.1200	0.96	1.35	1.51	2.05
1.2	1.1800	1.2200	0.87	1.23	1.41	1.93
1.3	1.2800	1.3200	0.77	1.12	1.33	1.83
1.4	1.3800	1.4200	0.69	1.01	1.24	1.72
1.5	1.4800	1.5200	0.62	0.91	1.17	1.63
1.6	1.5800	1.6200	0.56	0.84	1.10	1.54
1.7	1.6800	1.7200	0.51	0.77	1.04	1.47
1.8	1.7800	1.8200	0.47	0.72	0.99	1.40
1.9	1.8800	1.9200	0.42	0.64	0.92	1.29
2.0	1.9800	2.0200	0.37	0.58	0.86	1.20
2.1	2.0790	2.1210				
2.2	2.1780	2.2220	0.31	0.47	0.75	1.05
2.3	2.2770	2.3230				
2.4	2.3760	2.4240	0.26	0.40	0.67	0.92
2.5	2.4750	2.5250				
2.6	2.5740	2.6260	0.23	0.34	0.60	0.82
2.7	2.6730	2.7270				
2.8	2.7720	2.8280	0.20	0.30	0.54	0.74
2.9	2.8710	2.9290				
3.0	2.9700	3.0300	0.17	0.26	0.50	0.67
3.1	3.0690	3.1310				
3.2	3.1680	3.2320				
3.3	3.2670	3.3330				
3.4	3.3660	3.4340				
3.5	3.4650	3.5350	0.15	0.22	0.43	0.59
3.6	3.5640	3.6360				
3.7	3.6630	3.7370				
3.8	3.7620	3.8380				
3.9	3.8610	3.9390				
4.0	3.9600	4.0400	0.13	0.19	0.38	0.51
4.1	4.0590	4.1410				
4.2	4.1580	4.2420				
4.3	4.2570	4.3430				
4.4	4.3560	4.4440				
4.5	4.4550	4.5450	0.11	0.17	0.35	0.47
4.6	4.5540	4.6460				
4.7	4.6530	4.7470				
4.8	4.7520	4.8480				
4.9	4.8510	4.9490				
5.0	4.9500	5.0500	0.10	0.16	0.32	0.43

■TEST CIRCUITS

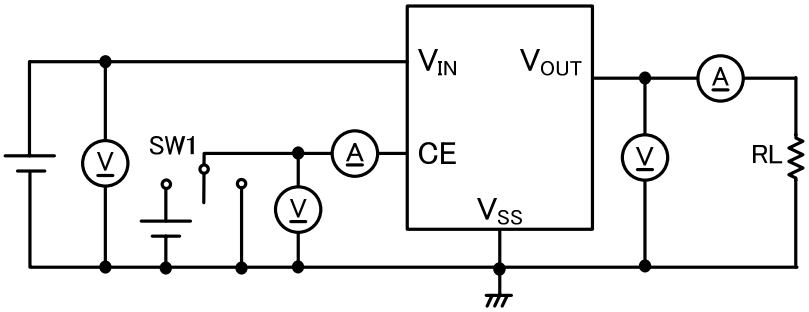
Circuit ①



Circuit ②

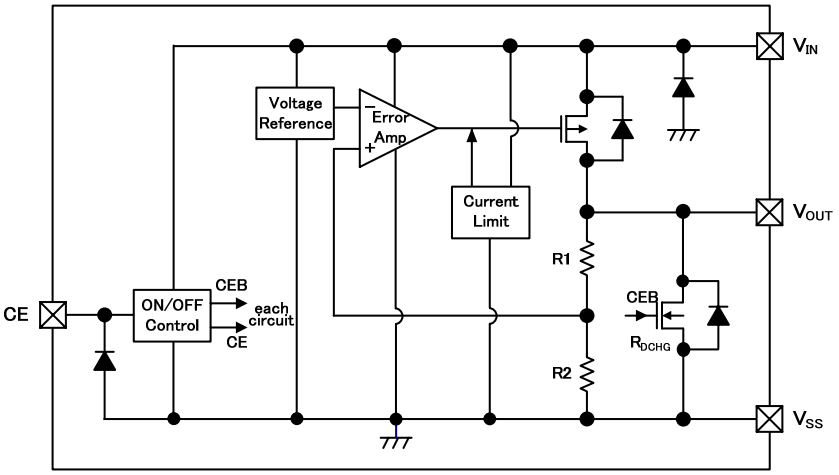


Circuit ③



■ OPERATIONAL EXPLANATION

The voltage divided by resistors R1 & R2 is compared with the internal reference voltage by the error amplifier. The VOUT pin is then driven by the subsequent output signal. The output voltage at the VOUT pin is controlled and stabilized by a system of negative feedback.



XC6504 Series, Type A

<Current Limiter, Short-Circuit Protection>

The XC6504 series includes a combination of a fixed current limiter circuit & a foldback circuit, which aid the operations of the current limiter and circuit protection. When the load current reaches the current limit level, the fixed current limiter circuit operates and output voltage drops. As a result of this drop in output voltage, the foldback circuit operates, output voltage drops further and output current decreases.

<CE Pin>

The XC6504 internal circuitry can be shutdown via the signal from the CE pin with the XC6504 series. In shutdown mode with CE low level voltage is input, output at the V_{OUT} pin will be pulled down to the V_{SS} level via parallel to R1 & R2 and C_L discharge resistance (R_{DCHG}).

If this IC is used with the correct output voltage for the CE pin, the logic is fixed and the IC will operate normally. However, supply current may increase as a result of through current in the IC's internal circuitry when medium voltage is input. The output voltage becomes unstable when the CE pin is opened.

<CL Auto-Discharge Function>

The XC6504 series can quickly discharge the electric charge at the output capacitor (C_L), when a low signal to the CE pin, which enables a whole IC circuit put into OFF state, is inputted via an internal switch located between the V_{OUT} pin and the V_{SS} pin. In this state, the application is protected from a glitch operation caused by the electric charge at the output capacitor (C_L). Moreover, discharge time of the output capacitor (C_L) is set by the C_L auto-discharge resistance (R_{DCHG}) and the output capacitor (C_L). By setting time constant of a C_L auto-discharge resistance value (R_{DCHG}) and an output capacitor value (C_L) as τ ($\tau = C_L \times R_{DCHG}$), the output voltage after discharge via the internal switch is calculated by the following formulas. Please also note R_{DCHG} is depended on V_{IN} and When V_{IN} is high, R_{DCHG} is low.

$$V = V_{OUT(E)} \times e^{-t/\tau} \quad or \quad t = \tau \ln (V_{OUT(E)} / V)$$

V: Output voltage after discharge
$V_{OUT(E)}$: Output voltage
t: Discharge time
τ : $C_L \times R_{DCHG}$

<Low ESR Capacitors>

The XC6504 series can provide a stable output voltage even if without C_L capacitor or with a low ESR C_L capacitor because of a built-in phase compensation circuit. In case of adding a C_L capacitor, we suggest that an output capacitor (C_L) is connected as close as possible to the V_{OUT} pin and the V_{SS} pin. When V_{IN} stabilization is needed, please place an input capacitor (C_{IN}) as close as to the V_{IN} pin and the V_{SS} pin.

■NOTES ON USE

1. For temporary, transitional voltage drop or voltage rising phenomenon, the IC is liable to malfunction should the ratings be exceeded.

2. Where wiring impedance is high, operations may become unstable due to noise and/or phase lag depending on output current. Please keep the resistance low between V_{IN} and V_{SS} wiring in particular.

3. Please wire the input capacitor (C_{IN}) and the output capacitor (C_L) as close to the IC as possible.

4. Capacitances of these capacitors (C_{IN}, C_L) are decreased by the influences of bias voltage and ambient temperature. Care shall be taken for capacitor selection to ensure stability of phase compensation from the point of ESR influence.

5. Torex places an importance on improving our products and their reliability.
   We request that users incorporate fail-safe designs and post-aging prevention treatment when using Torex products in their systems.

■TYPICAL PERFORMANCE CHARACTERISTICS

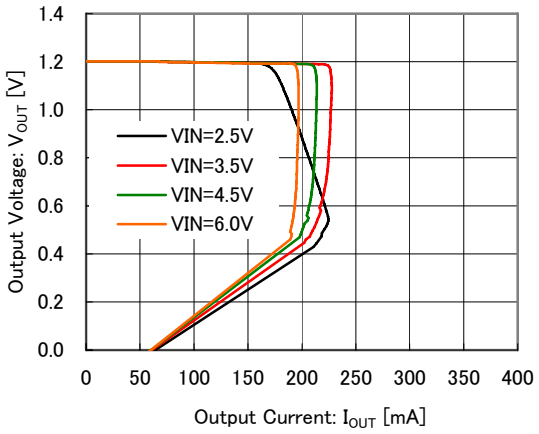
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V ： V_{IN}=3.5V

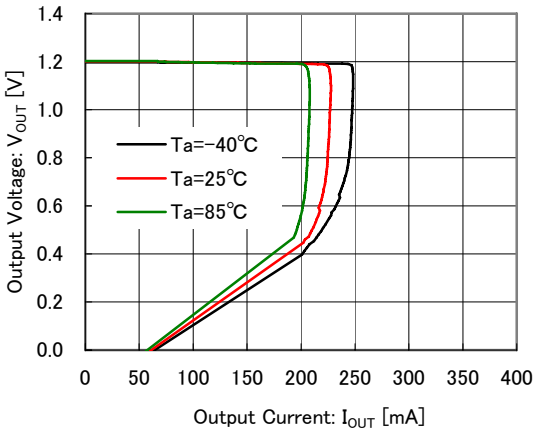
$V_{OUT(T)}$≧2.5V ： V_{IN}=$V_{OUT(T)}$+1.0V

(1) Output Voltage vs. Output Current

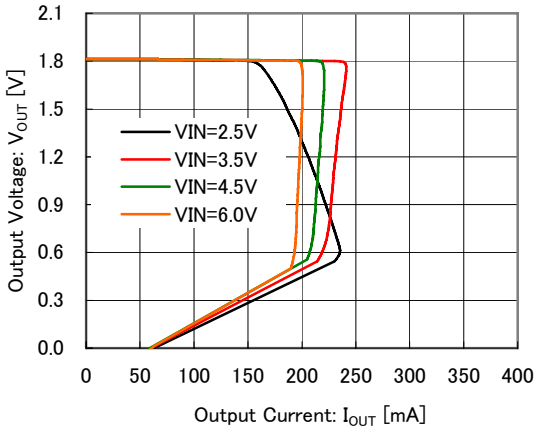
XC6504x121xR



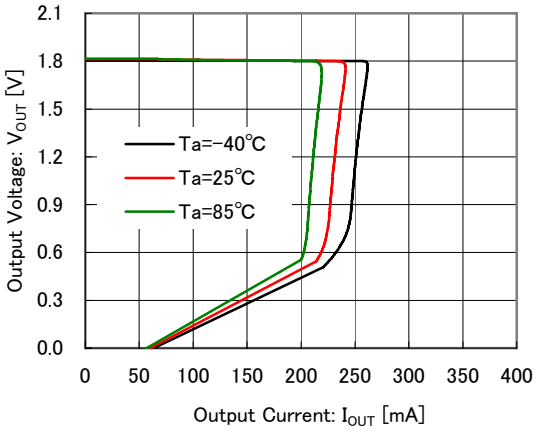
XC6504x121xR



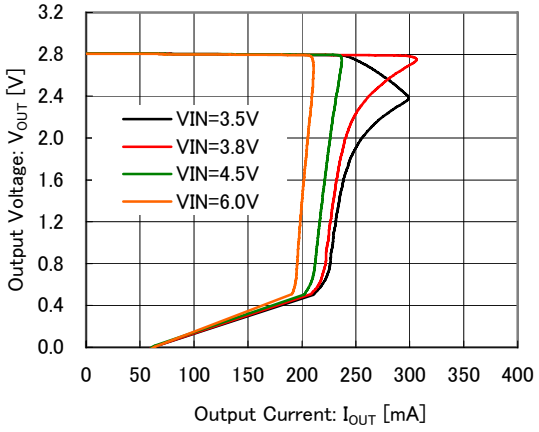
XC6504x181xR



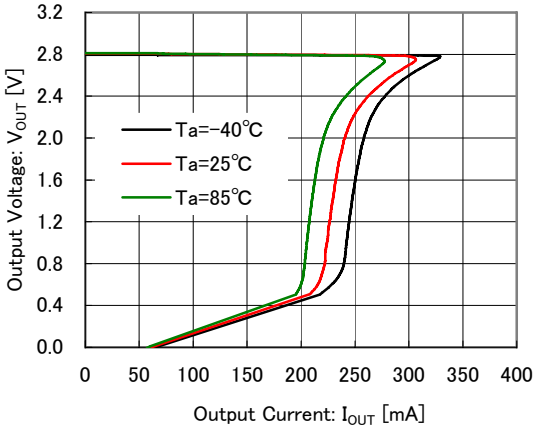
XC6504x181xR



XC6504x281xR



XC6504x281xR



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

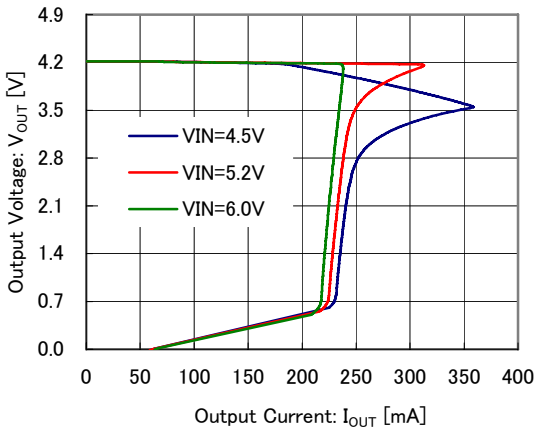
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V : V_{IN}=3.5V

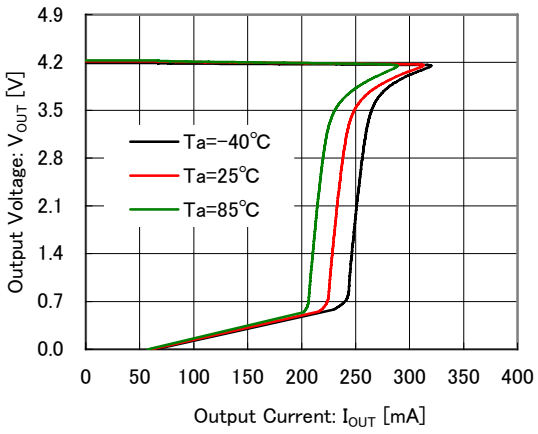
$V_{OUT(T)}$≧2.5V : V_{IN}=$V_{OUT(T)}$+1.0V

(1) Output Voltage vs. Output Current

XC6504x421xR

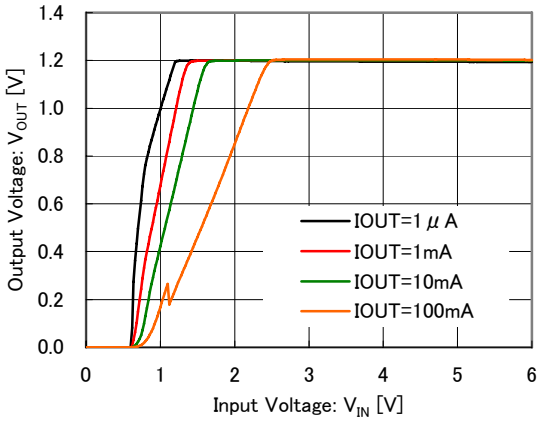


XC6504x421xR



(2) Output Voltage vs. Input Voltage

XC6504x121xR



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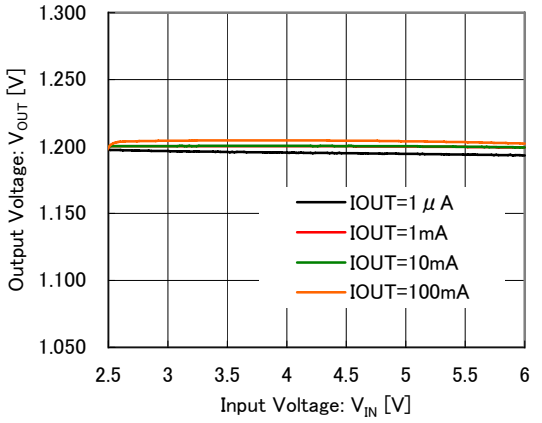

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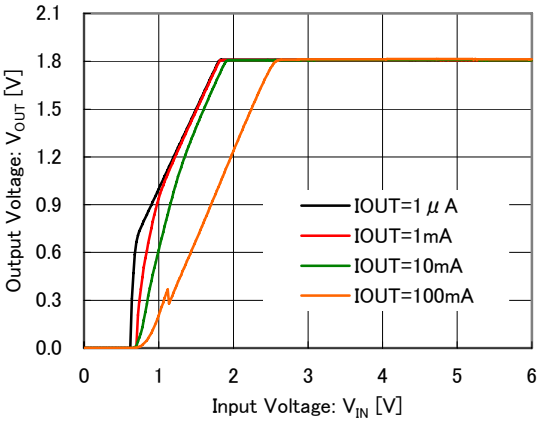

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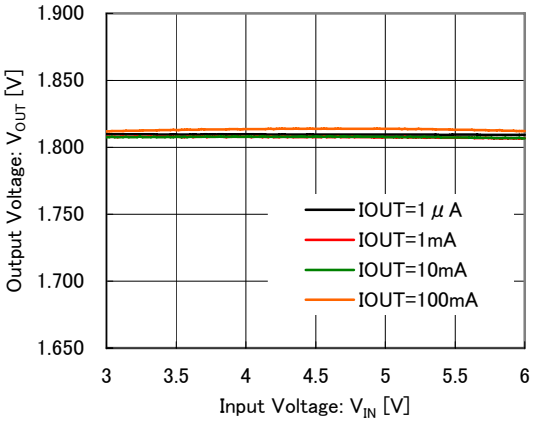


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

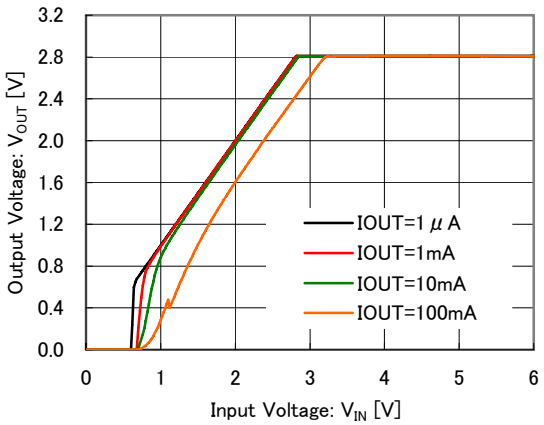
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V : V_{IN}=3.5V

$V_{OUT(T)}$≧2.5V : V_{IN}=$V_{OUT(T)}$+1.0V

(2) Output Voltage vs. Input Voltage

XC6504x281xR



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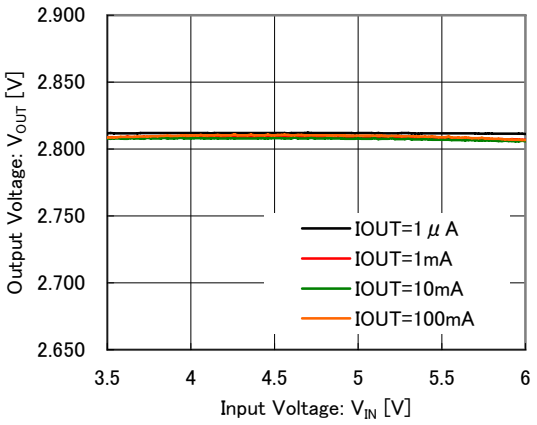
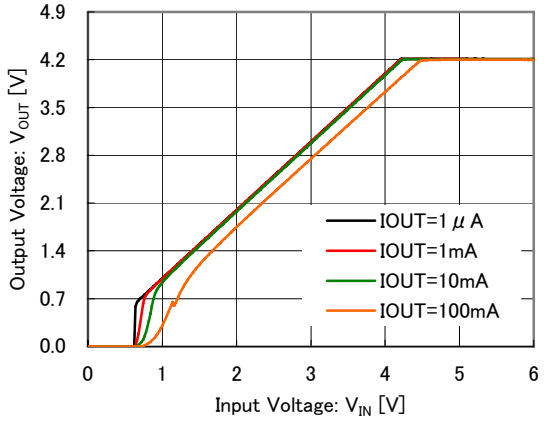


XC6504x421xR



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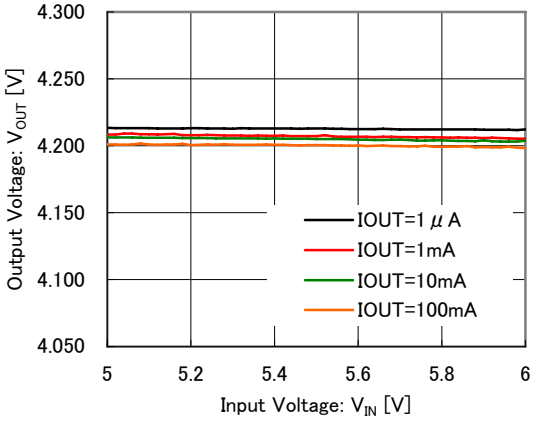
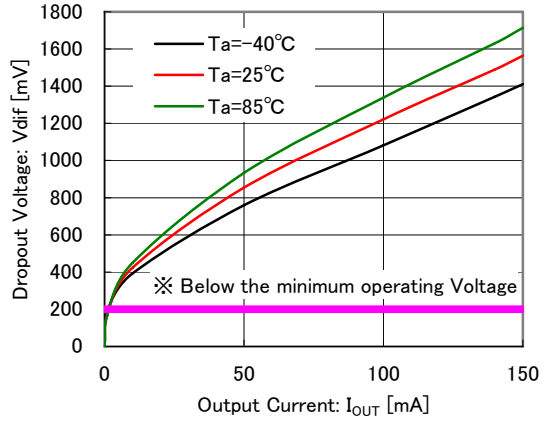


(3) Dropout Voltage vs. Output Current

XC6504x121xR



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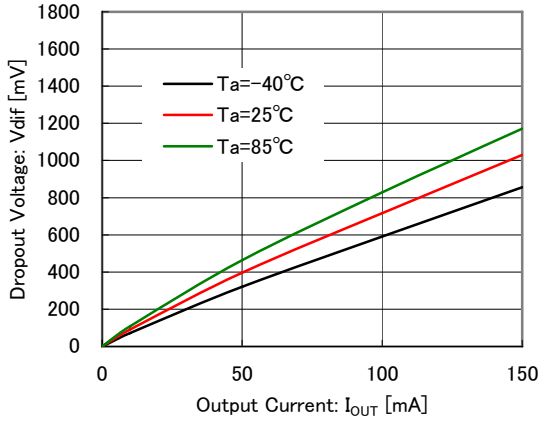


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

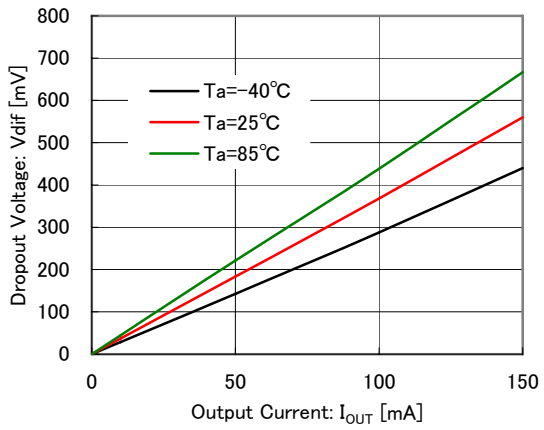
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V : V_{IN}=3.5V

$V_{OUT(T)}$≧2.5V : V_{IN}=$V_{OUT(T)}$+1.0V

(3) Dropout Voltage vs. Output Current

XC6504x281xR



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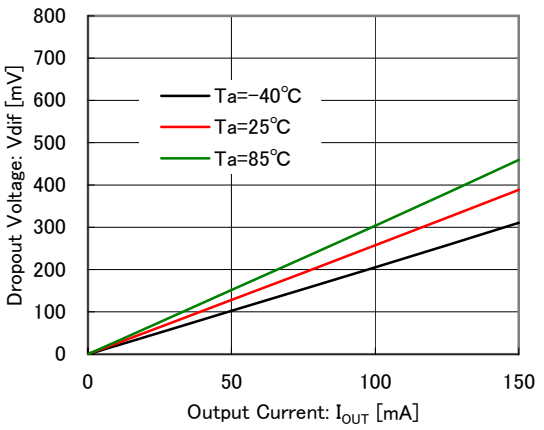
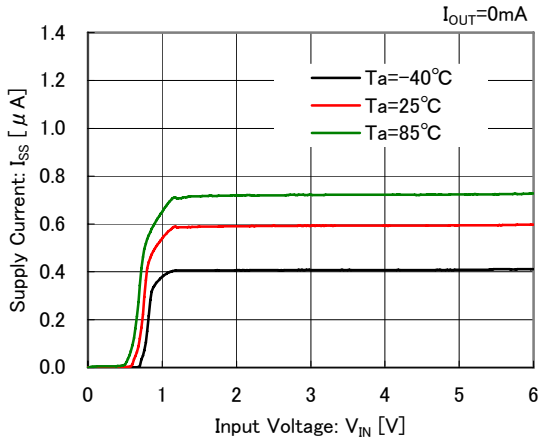
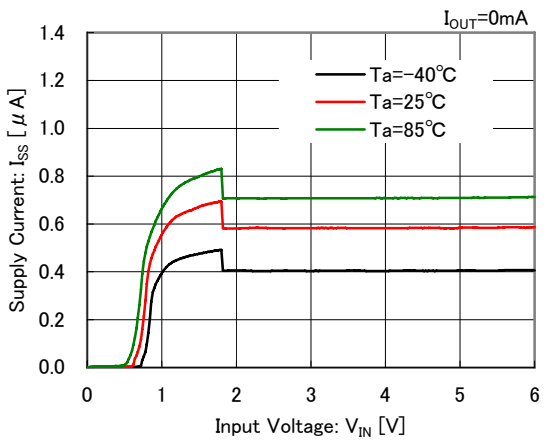


(4) Supply Current vs. Input Voltage

XC6504x121xR



XC6504x181xR



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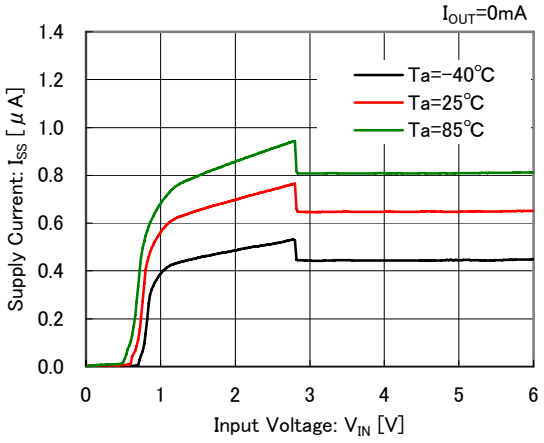

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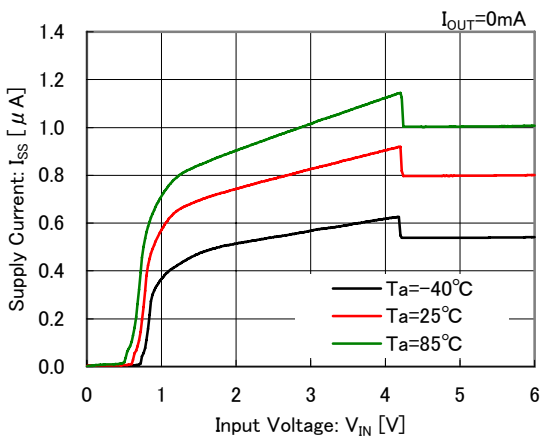


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

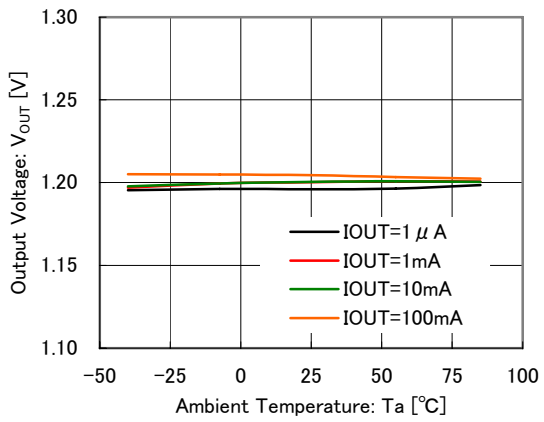
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V : V_{IN}=3.5V

$V_{OUT(T)}$≧2.5V : V_{IN}=$V_{OUT(T)}$+1.0V

(5) Output Voltage vs. Ambient Temperature

XC6504x121xR



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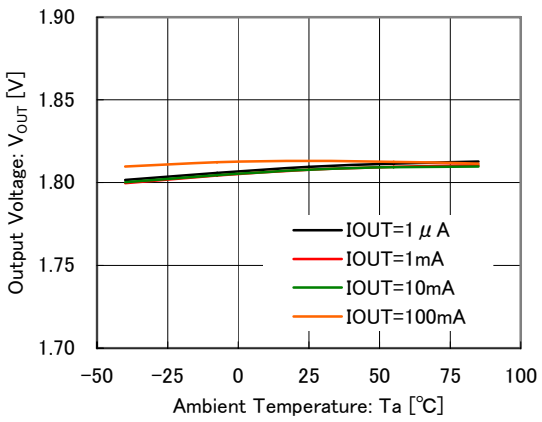
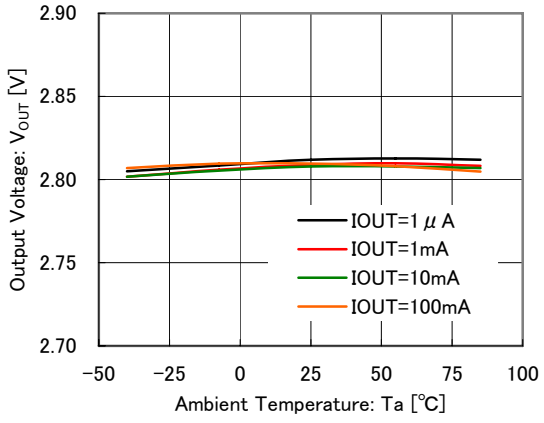


XC6504x281xR



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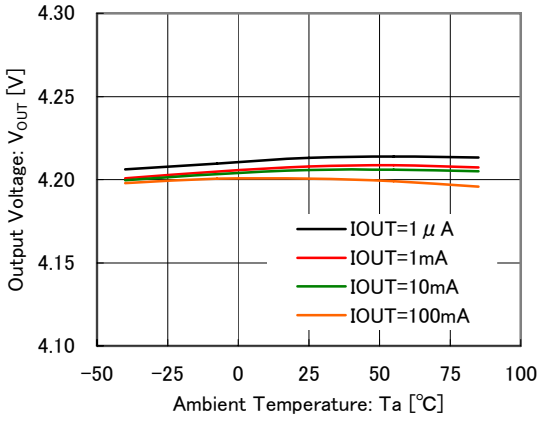
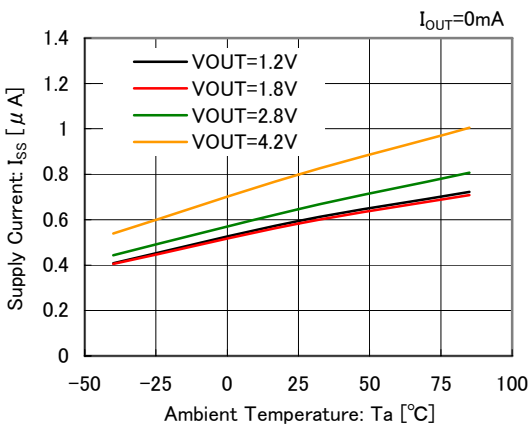


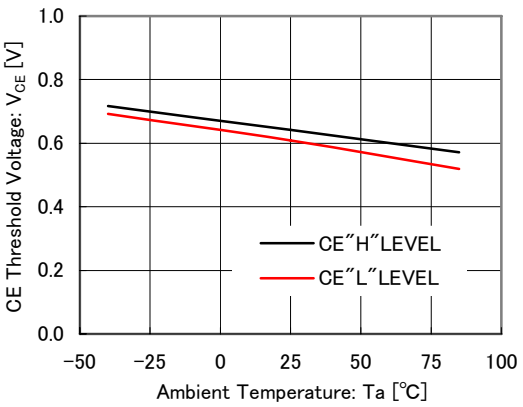
(6) Supply Current vs. Ambient Temperature

XC6504xxx1xR



(7) CE Threshold Voltage vs. Ambient Temperature

XC6504xxx1xR



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

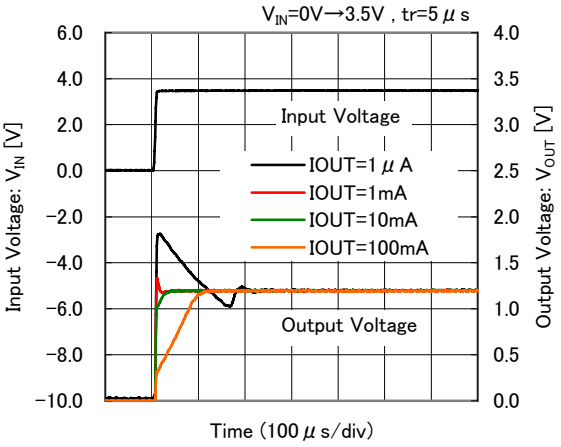
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V ： V_{IN}=3.5V

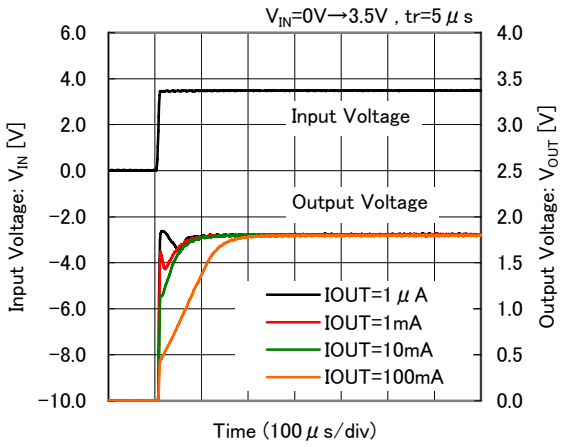
$V_{OUT(T)}$≧2.5V ： V_{IN}=$V_{OUT(T)}$+1.0V

(8) Rising Response Time

XC6504x121xR



XC6504x181xR



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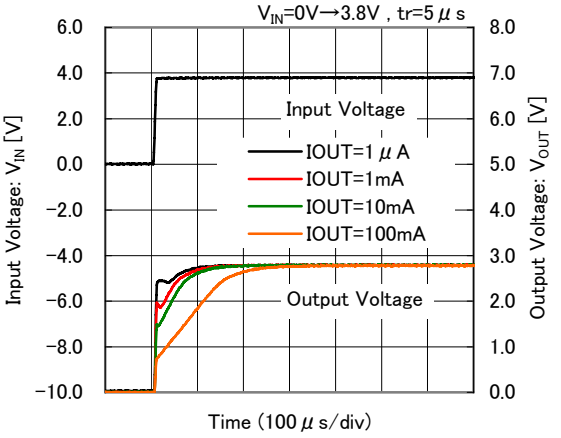

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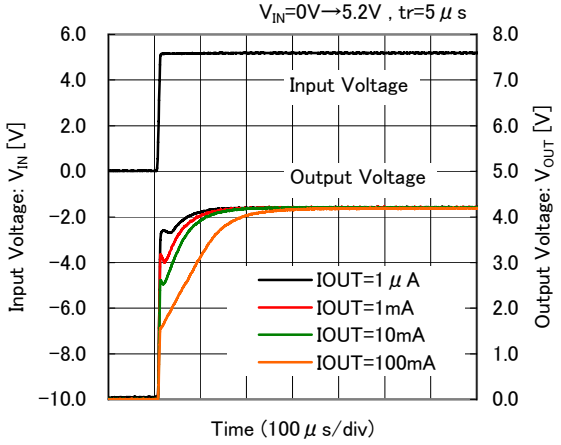
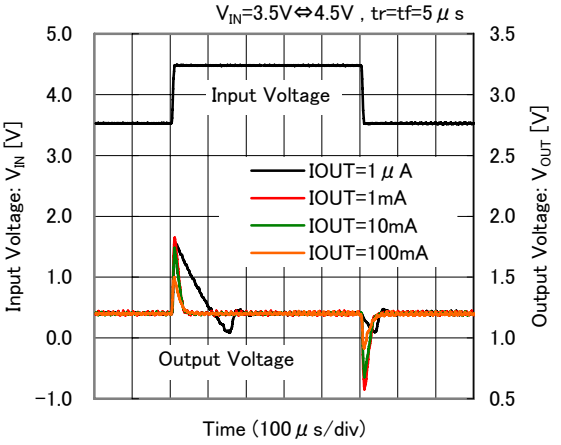
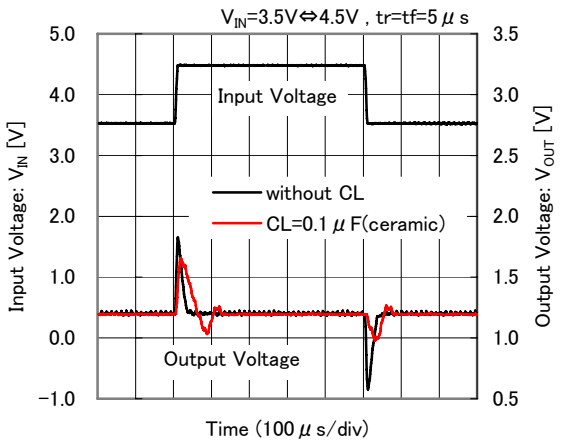


(9) Input Transient Response

XC6504x121xR



XC6504x121xR



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

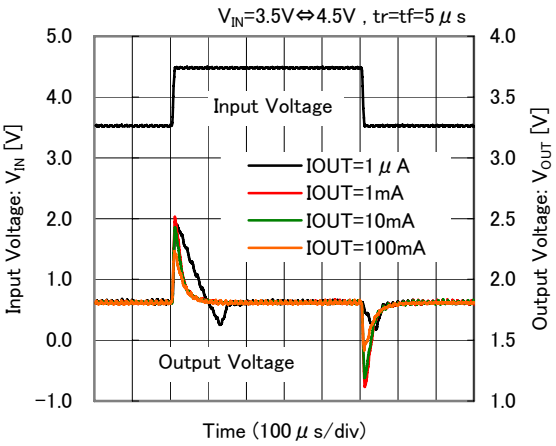
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V ： V_{IN}=3.5V

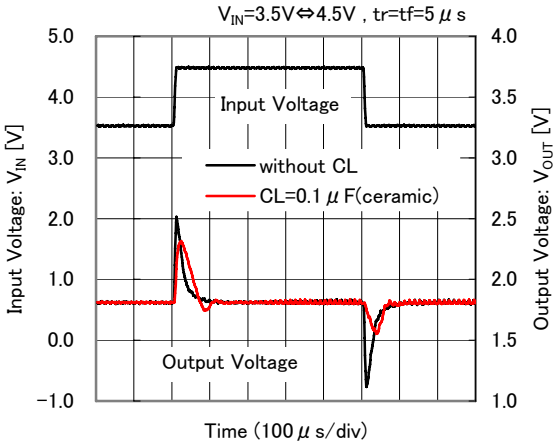
$V_{OUT(T)}$≧2.5V ： V_{IN}=$V_{OUT(T)}$+1.0V

(9) Input Transient Response

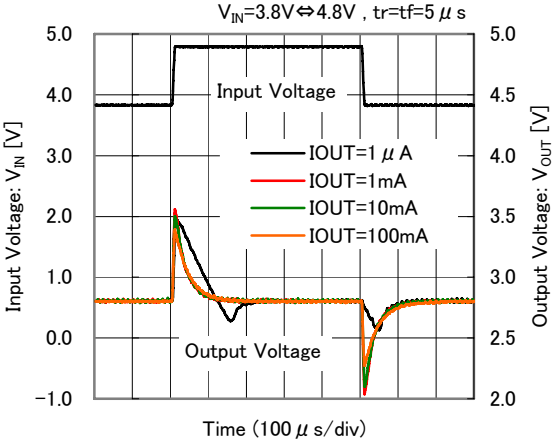
XC6504x181xR



XC6504x181xR



XC6504x281xR



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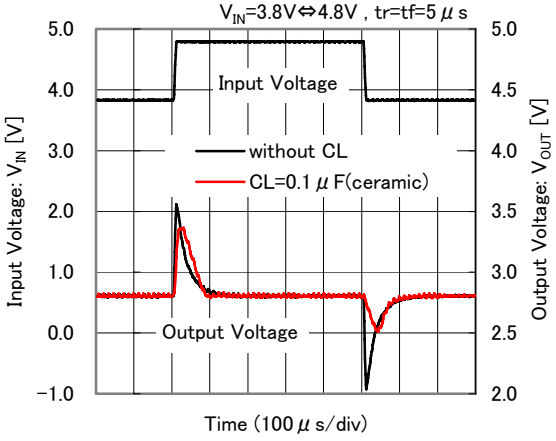

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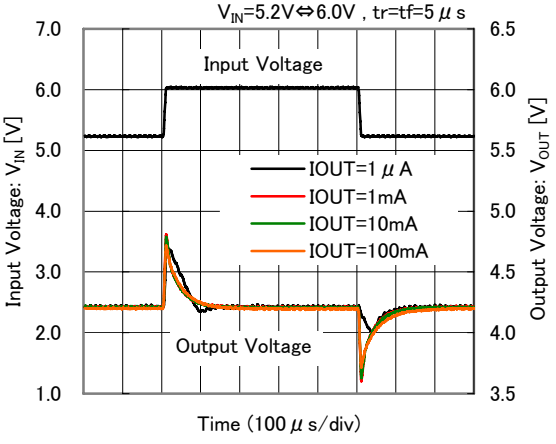

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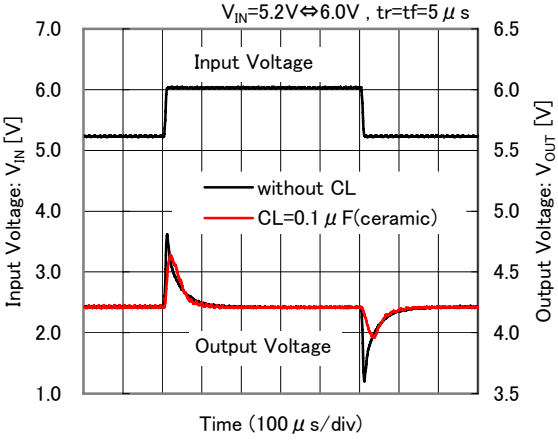


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

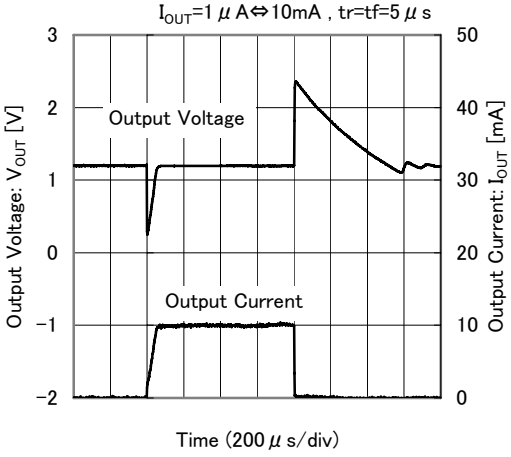
$V_{OUT(T)}$＜2.5V ： V_{IN}=3.5V

$V_{OUT(T)}$≧2.5V ： V_{IN}=$V_{OUT(T)}$+1.0V

(10) Load Transient Response

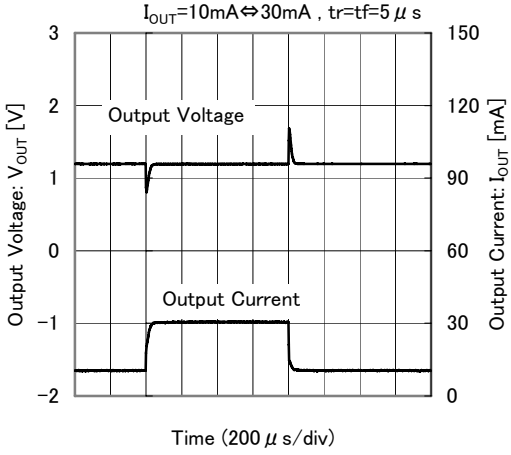
XC6504x121xR

I_{OUT}=1μA⇔10mA , tr=tf=5μs



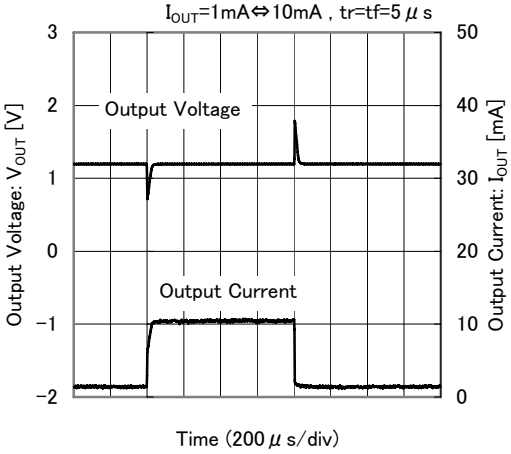
XC6504x121xR

I_{OUT}=10mA⇔30mA , tr=tf=5μs



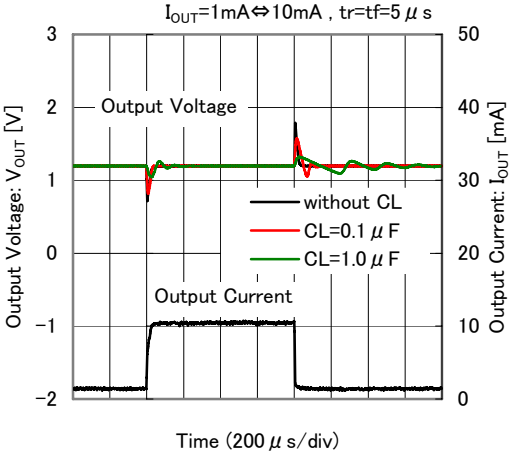
XC6504x121xR

I_{OUT}=1mA⇔10mA , tr=tf=5μs



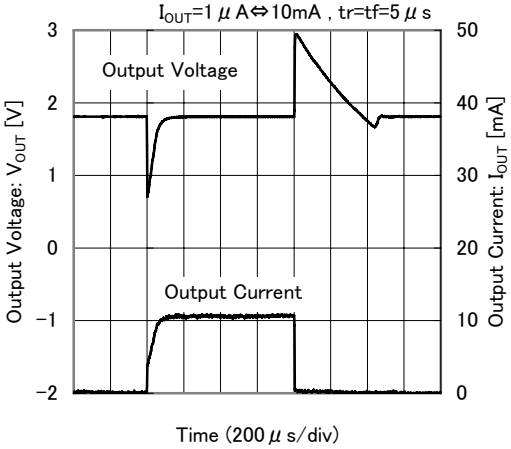
XC6504x121xR

I_{OUT}=1mA⇔10mA , tr=tf=5μs



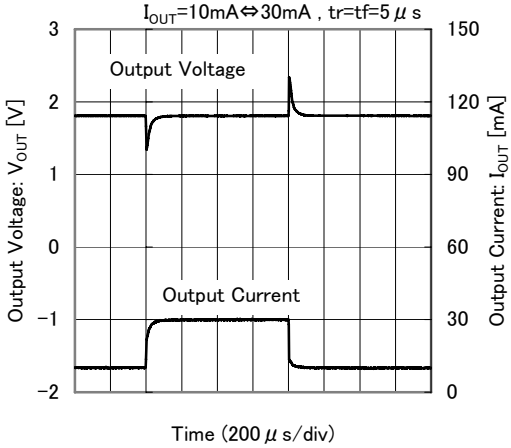
XC6504x181xR

I_{OUT}=1μA⇔10mA , tr=tf=5μs



XC6504x181xR

I_{OUT}=10mA⇔30mA , tr=tf=5μs



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

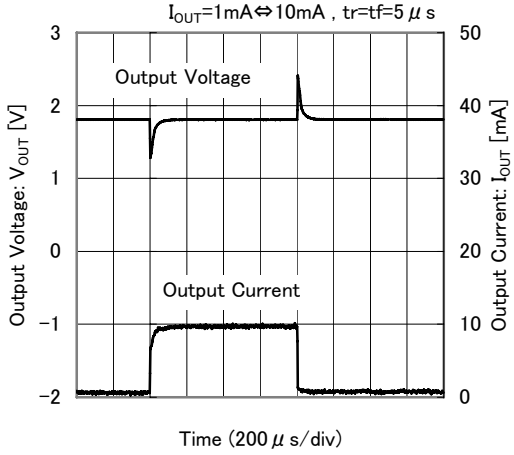
$V_{OUT(T)}$＜2.5V ： V_{IN}=3.5V

$V_{OUT(T)}$≧2.5V ： V_{IN}=$V_{OUT(T)}$+1.0V

(10) Load Transient Response

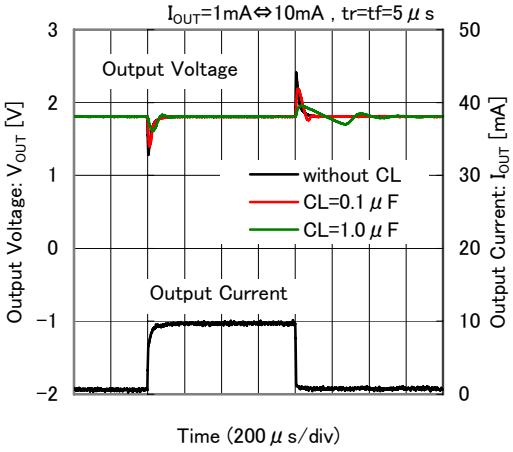
XC6504x181xR

I_{OUT}=1mA⇔10mA , tr=tf=5μs



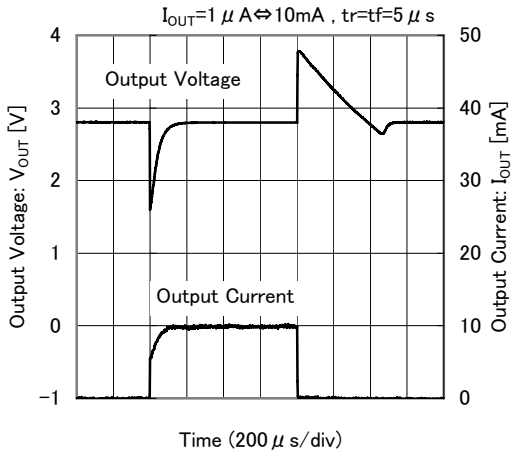
XC6504x181xR

I_{OUT}=1mA⇔10mA , tr=tf=5μs



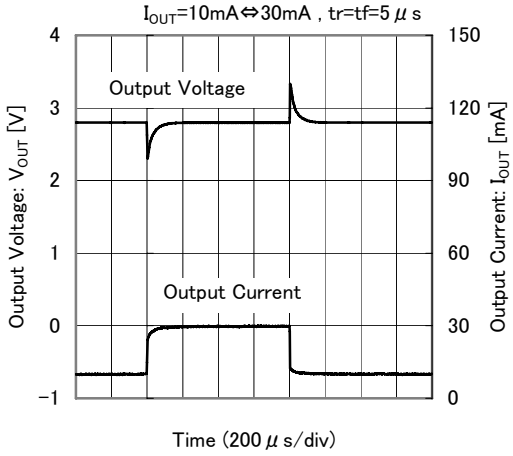
XC6504x281xR

I_{OUT}=1μA⇔10mA , tr=tf=5μs



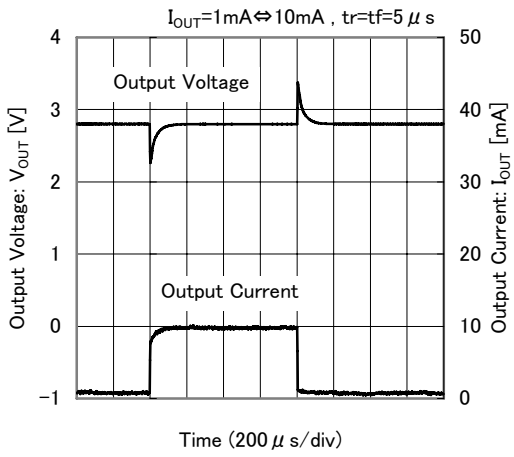
XC6504x281xR

I_{OUT}=10mA⇔30mA , tr=tf=5μs



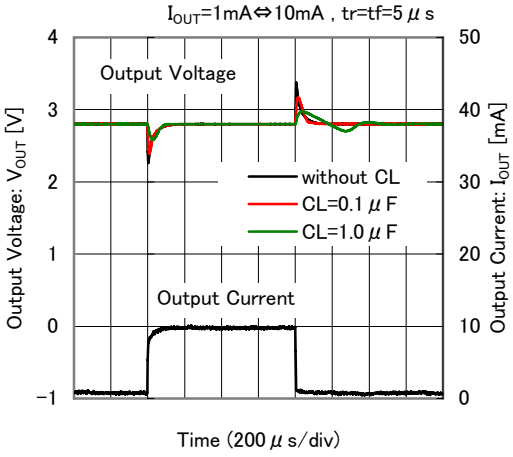
XC6504x281xR

I_{OUT}=1mA⇔10mA , tr=tf=5μs



XC6504x281xR

I_{OUT}=1mA⇔10mA , tr=tf=5μs



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

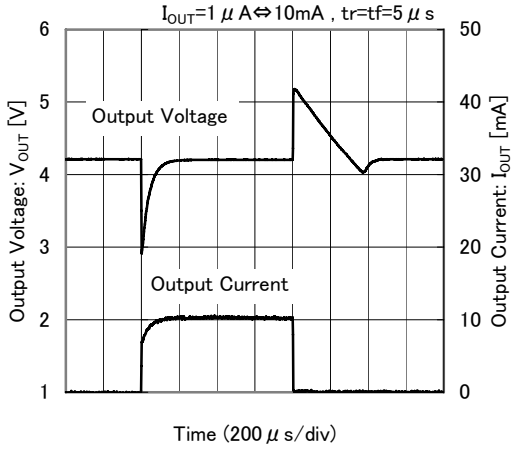
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V ： V_{IN}=3.5V

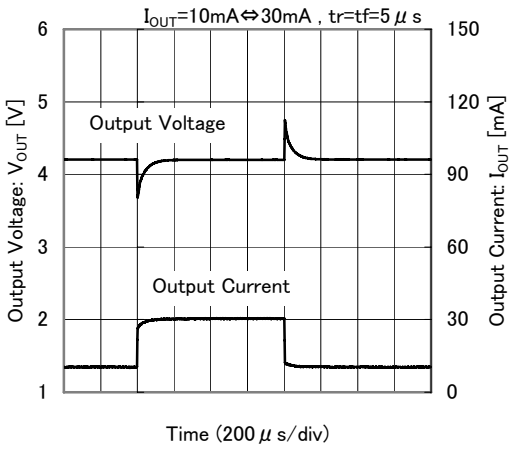
$V_{OUT(T)}$≧2.5V ： V_{IN}=$V_{OUT(T)}$+1.0V

(10) Load Transient Response

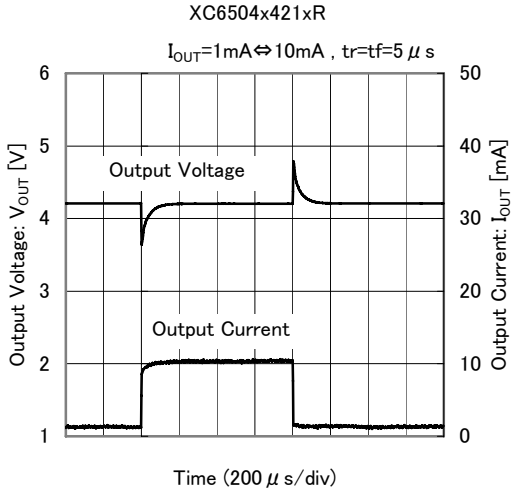
XC6504x421xR



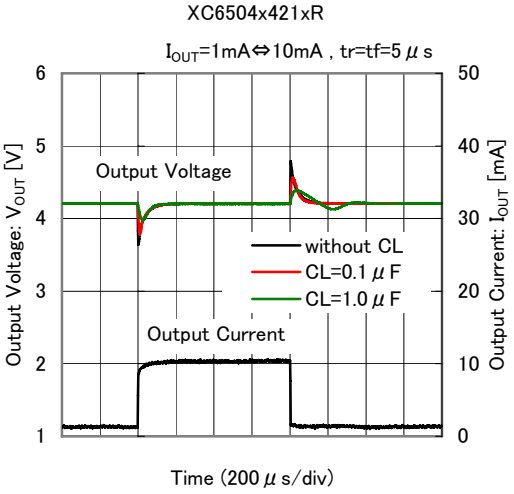
XC6504x421xR



XC6504x421xR

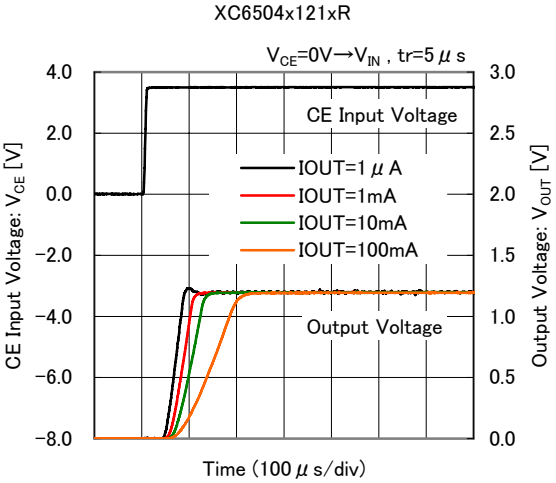


XC6504x421xR

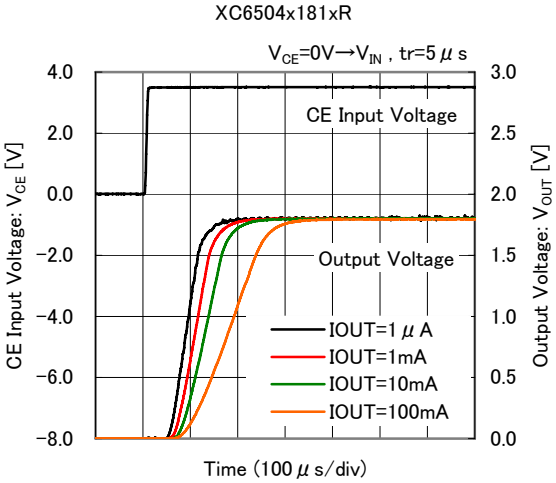


(11) CE Rising Response Time

XC6504x121xR



XC6504x181xR



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

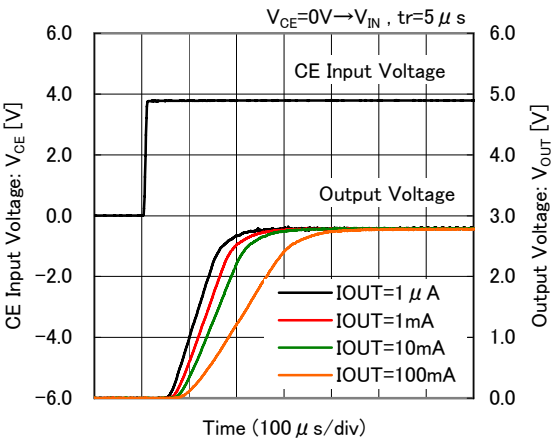
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

$V_{OUT(T)}$＜2.5V ： V_{IN}=3.5V

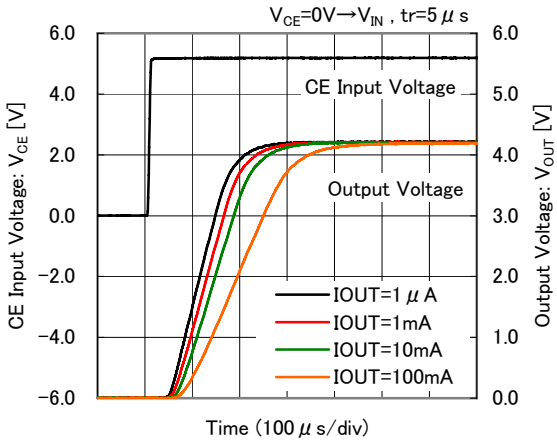
$V_{OUT(T)}$≧2.5V ： V_{IN}=$V_{OUT(T)}$+1.0V

(11) CE Rising Response Time

XC6504x281xR

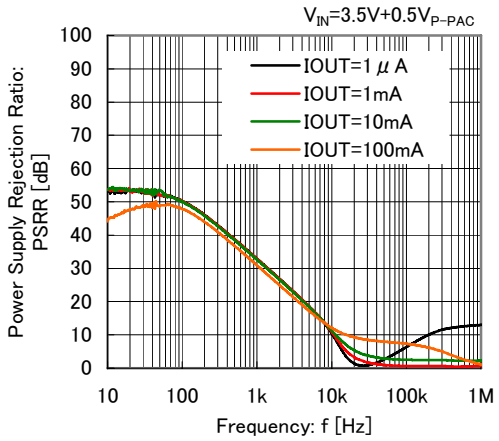


XC6504x421xR

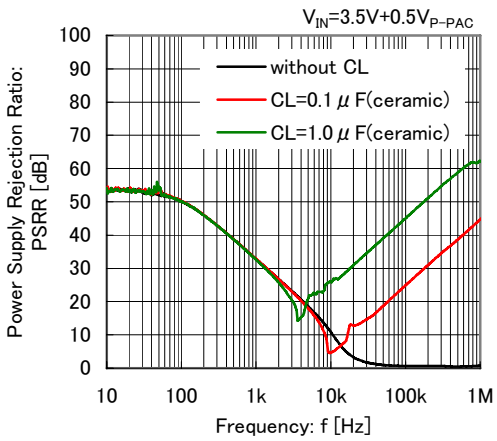


(12) Power Supply Rejection Ratio

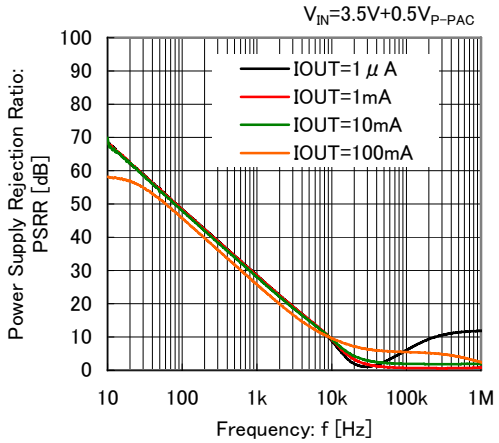
XC6504x121xR



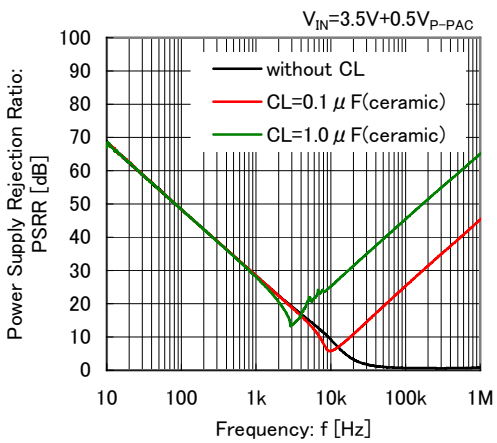
XC6504x121xR



XC6504x181xR



XC6504x181xR



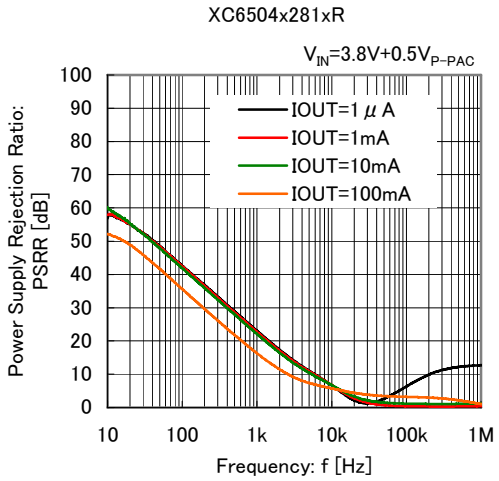
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

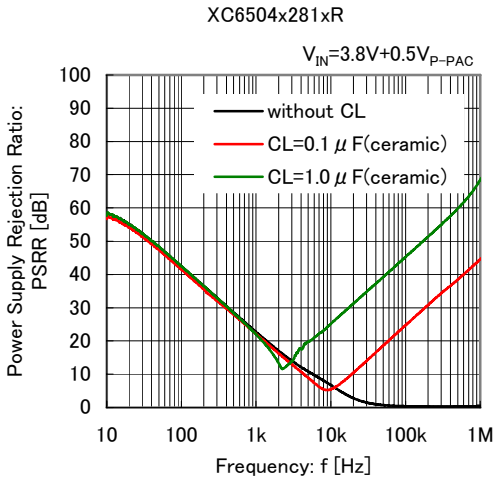
Unless otherwise stated, Ta=25℃, V_{CE}=V_{IN}, I_{OUT}=1mA, C_{IN}=C_L=open, V_{IN} is below.

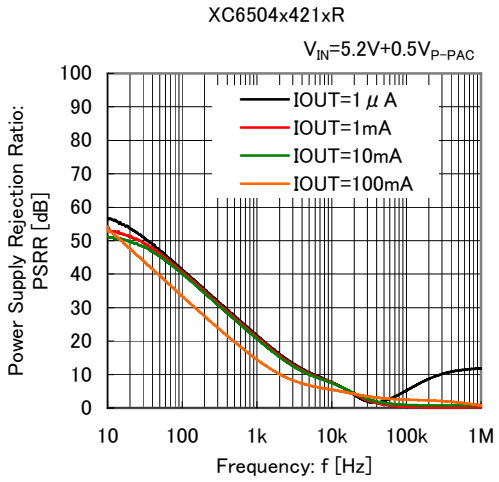
$V_{OUT(T)}$＜2.5V ： V_{IN}=3.5V

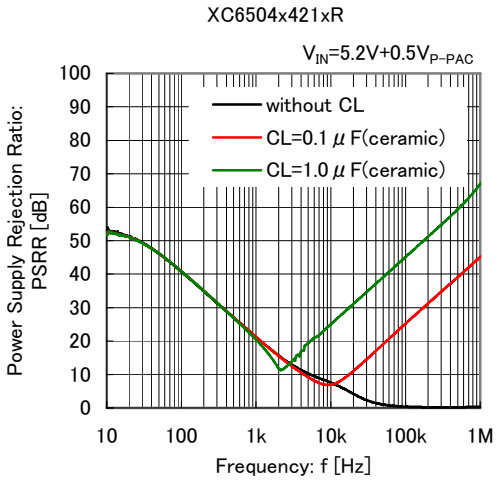
$V_{OUT(T)}$≧2.5V ： V_{IN}=$V_{OUT(T)}$+1.0V

(12) Power Supply Rejection Ratio



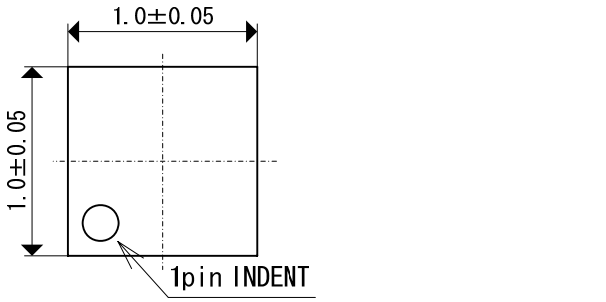


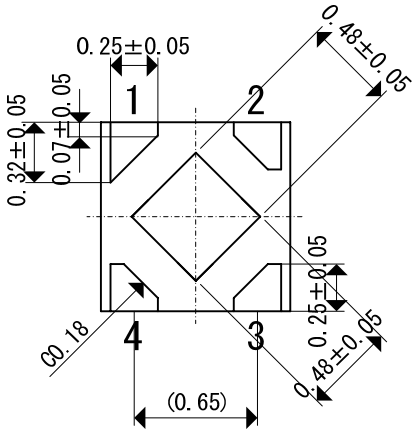




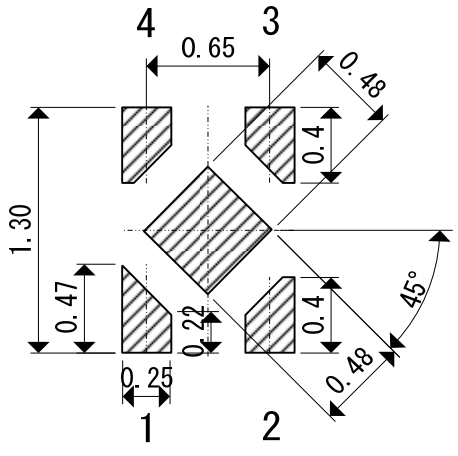
■PACKAGING INFORMATION

●USPQ-4B04 (unit:mm)

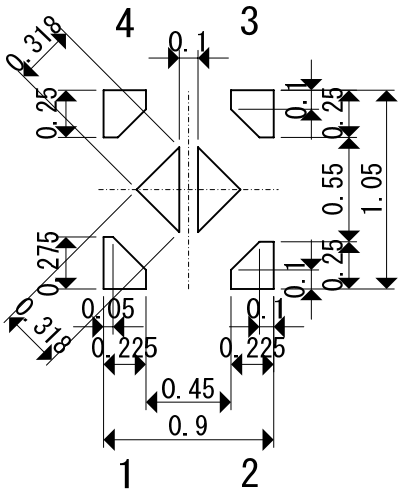




●USPQ-4B04 Reference Pattern Layout

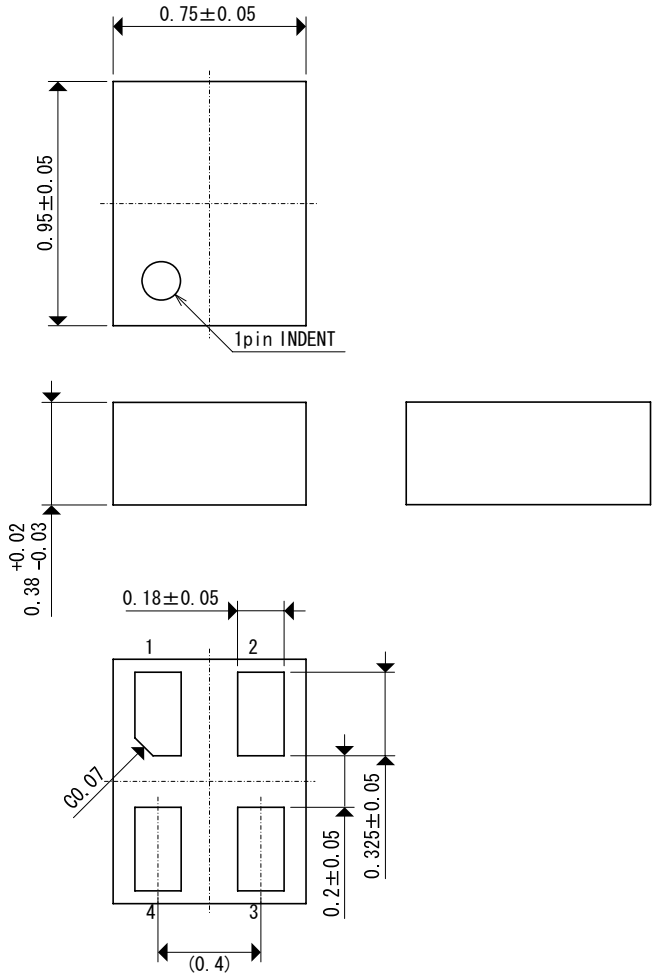


●USPQ-4B04 Reference Metal Mask Design

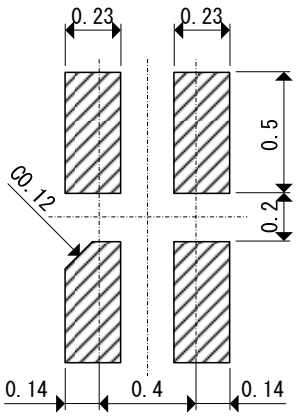


■PACKAGING INFORMATION (Continued)

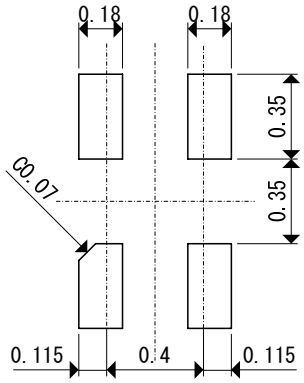
●USPN−4B02 (unit：mm)



●USPN-4B02 Reference Pattern Layout

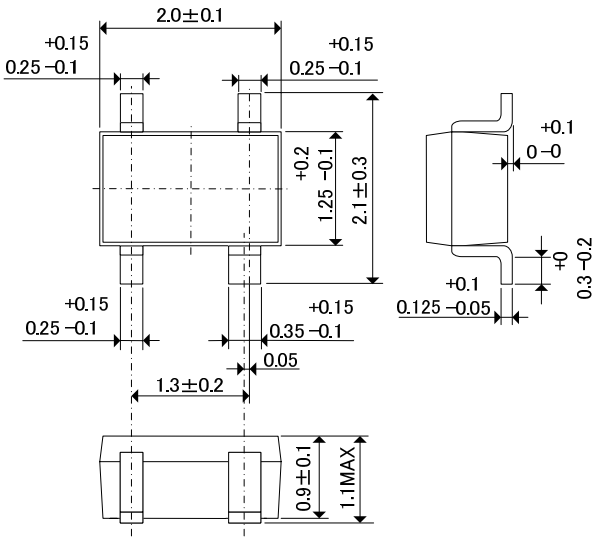


●USPN-4B02 Reference Metal Mask Design

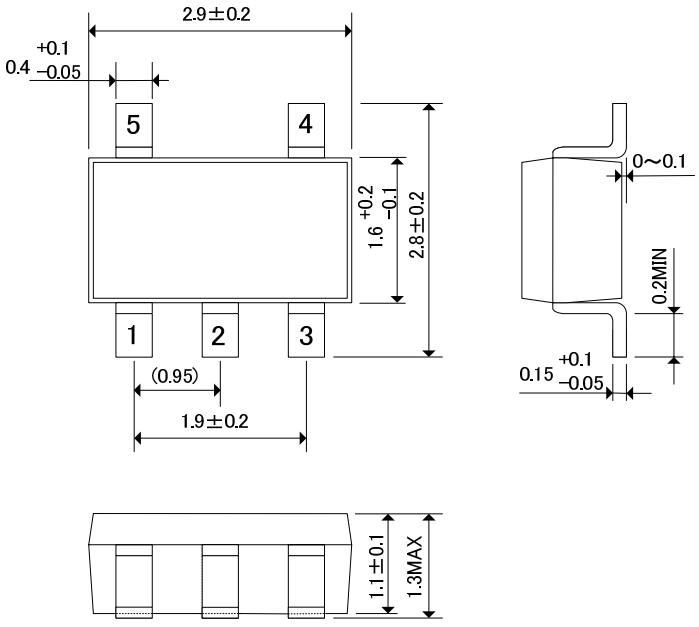


■PACKAGING INFORMATION (Continued)

●SSOT-24 (unit:mm)



●SOT-25 (unit:mm)



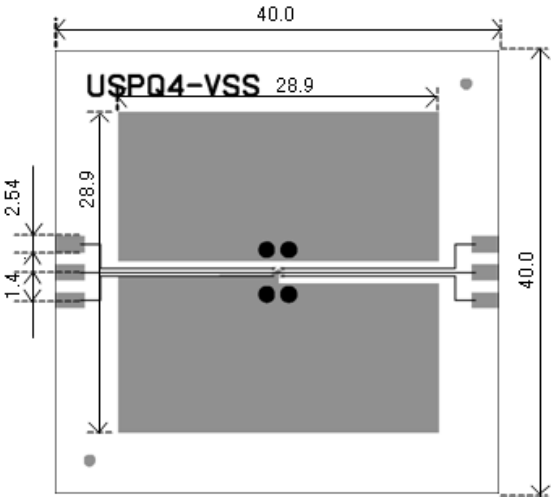
■PACKAGING INFORMATION (Continued)

● USPQ-4B04 Power Dissipation

Power dissipation data for the USPQ-4B04 is shown in this page.
The value of power dissipation varies with the mount board conditions.
Please use this data as the reference data taken in the following condition.

1. Measurement Condition

Condition	: Mount on a board
Ambient	: Natural convection
Soldering	: Lead (Pb) free
Board Dimensions	: 40 x 40 mm (1600mm^2)
Board Structure	: 4 Copper Layers Each layer is connected to the package heat-sink and terminal pin No.1. Each layer has approximately 800mm^2 copper area.
Material	: Glass Epoxy (FR-4)
Thickness	: 1.6 mm
Through-hole	: 4 x 0.8 Diameter

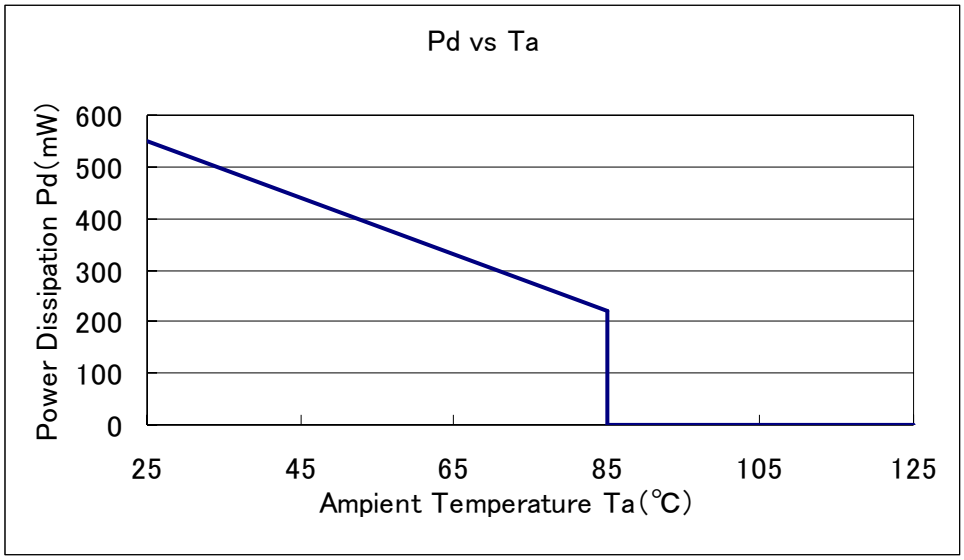


Evaluation Board (Unit: mm)

2. Power Dissipation vs. Ambient Temperature

Board Mount (Tj max = 125℃)

Ambient Temperature (℃)	Power Dissipation Pd (mW)	Thermal Resistance (℃/W)
25	550	181.82
85	220	



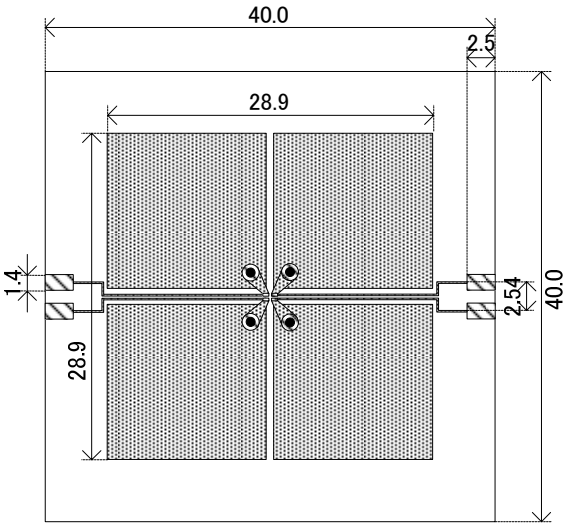
■PACKAGING INFORMATION (Continued)

● USPN-4B02 Power Dissipation

Power dissipation data for the USPN-4B02 is shown in this page.
The value of power dissipation varies with the mount board conditions.
Please use this data as the reference data taken in the following condition.

1. Measurement Condition

Condition:	Mount on a board
Ambient:	Natural convection
Soldering:	Lead (Pb) free
Board:	Dimensions 40 x 40 mm (1600mm^2 in one side)
	Copper (Cu) traces occupy 50% of the front and 50% of the back.
	The copper area is divided into four block,
	One block is 12.5% of total.
	The USPN-4B02 package has for terminals.
	Each terminal connects one copper block in the front and one in the back.
Material:	Glass Epoxy (FR-4)
Thickness:	1.6 mm
Through-hole:	4 x 0.8 Diameter

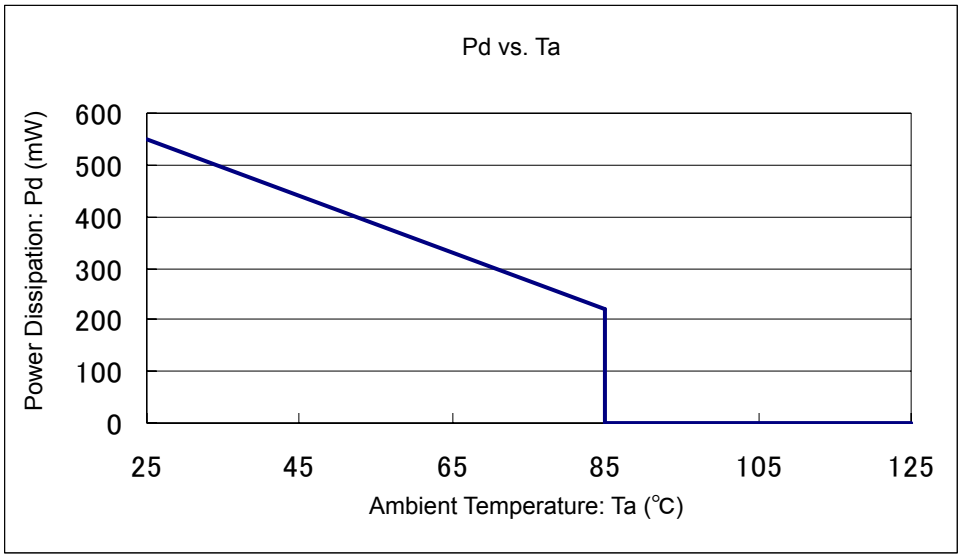


Evaluation Board (Unit: mm)

2. Power Dissipation vs. Ambient Temperature

Board Mount (Tjmax=125℃)

Ambient Temperature (℃)	Power Dissipation Pd (mW)	Thermal Resistance (℃/W)
25	550	181.82
85	220	



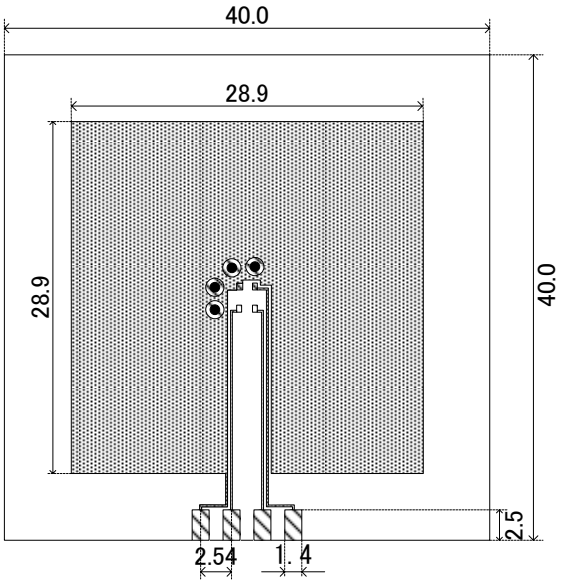
■PACKAGING INFORMATION (Continued)

● SSOT-24 Power Dissipation

Power dissipation data for the SSOT-24 is shown in this page.
The value of power dissipation varies with the mount board conditions.
Please use this data as the reference data taken in the following condition.

1. Measurement Condition

Condition:	Mount on a board
Ambient:	Natural convection
Soldering:	Lead (Pb) free
Board:	Dimensions 40 x 40 mm (1600 mm^2 in one side)
	Copper (Cu) traces occupy 50% of the board area
	In top and back faces
	Package heat-sink is tied to the copper traces
Material:	Glass Epoxy (FR-4)
Thickness:	1.6 mm
Through-hole:	4 x 0.8 Diameter

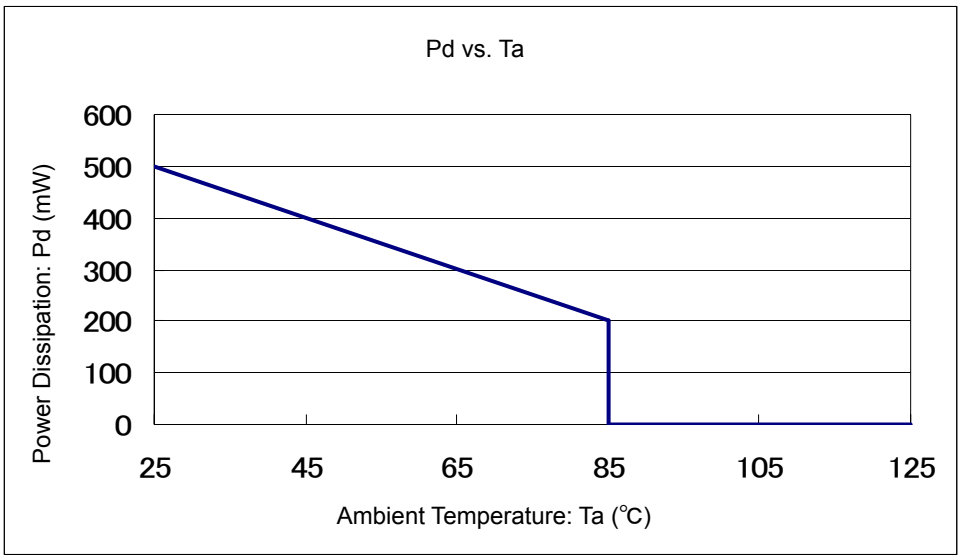


Evaluation Board (Unit: mm)

2. Power Dissipation vs. Ambient Temperature

Board Mount (Tj max = 125℃)

Ambient Temperature (℃)	Power Dissipation Pd (mW)	Thermal Resistance (℃/W)
25	500	200.00
85	200	



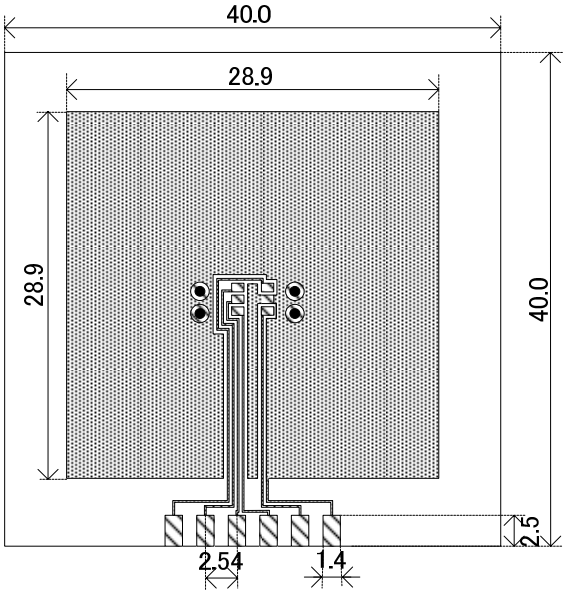
■PACKAGING INFORMATION (Continued)

● SOT-25 Power Dissipation

Power dissipation data for the SOT-25 is shown in this page.
The value of power dissipation varies with the mount board conditions.
Please use this data as the reference data taken in the following condition.

1. Measurement Condition

Condition:	Mount on a board
Ambient:	Natural convection
Soldering:	Lead (Pb) free
Board:	Dimensions 40 x 40 mm (1600 mm^2 in one side)
	Copper (Cu) traces occupy 50% of the board area
	In top and back faces
	Package heat-sink is tied to the copper traces
	(Board of SOT-26 is used.)
Material:	Glass Epoxy (FR-4)
Thickness:	1.6 mm
Through-hole:	4 x 0.8 Diameter

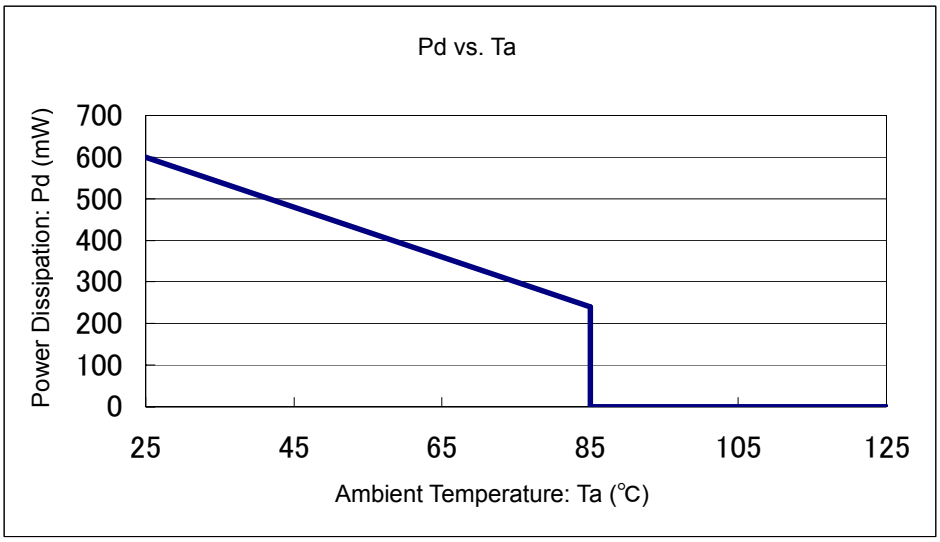


Evaluation Board (Unit: mm)

2. Power Dissipation vs. Ambient temperature

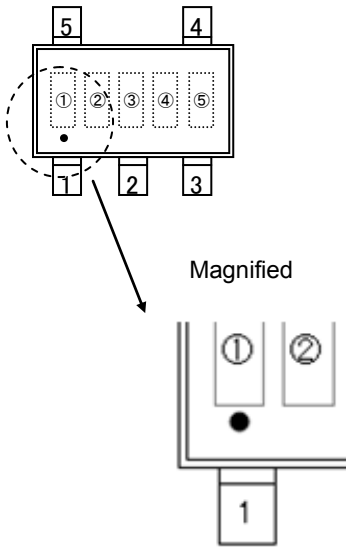
Board Mount (Tj max = 125℃)

Ambient Temperature(℃)	Power Dissipation Pd(mW)	Thermal Resistance (℃/W)
25	600	166.67
85	240	



■MARKING RULE

SOT-25 (Under-dot)



* SOT-25 with the under-dot marking is used.

① represents products series

MARK	PRODUCT SERIES
9	XC6504A*****-G

② represents output voltage range

MARK		PRODUCT SERIES
OUTPUT VOLTAGE 1.1V~3.9V	OUTPUT VOLTAGE 4.0V~5.0V	
A	B	XC6504A*****-G

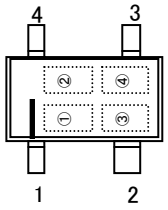
③ represents output voltage

MARK	OUTPUT VOLTAGE (V)		MARK	OUTPUT VOLTAGE (V)	
0	-	4.00	F	2.50	-
1	1.10	4.10	H	2.60	-
2	1.20	4.20	K	2.70	-
3	1.30	4.30	L	2.80	-
4	1.40	4.40	M	2.90	-
5	1.50	4.50	N	3.00	-
6	1.60	4.60	P	3.10	-
7	1.70	4.70	R	3.20	-
8	1.80	4.80	S	3.30	-
9	1.90	4.90	T	3.40	-
A	2.00	5.00	U	3.50	-
B	2.10	-	V	3.60	-
C	2.20	-	X	3.70	-
D	2.30	-	Y	3.80	-
E	2.40	-	Z	3.90	-

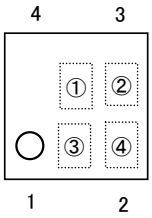
④,⑤ represents production lot number
01～09, 0A～0Z, 11～9Z, A1～A9, AA～AZ, B1～ZZ in order.
(G, I, J, O, Q, W excluded)
*No character inversion used.

■MARKING RULE (Continued)

●SSOT-24 (With the orientation bar at the bottom)



●USPQ-4B04



* SSOT-24 with the orientation bar at the bottom is used.

① represents output voltage range

MARK		PRODUCT SERIES
OUTPUT VOLTAGE 1.1V~3.9V	OUTPUT VOLTAGE 4.0V~5.0V	
P	R	XC6504A*****-G

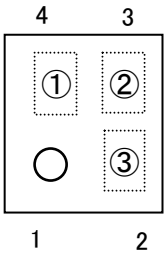
② represents output voltage

MARK	OUTPUT VOLTAGE (V)		MARK	OUTPUT VOLTAGE (V)	
0	-	4.00	F	2.50	-
1	1.10	4.10	H	2.60	-
2	1.20	4.20	K	2.70	-
3	1.30	4.30	L	2.80	-
4	1.40	4.40	M	2.90	-
5	1.50	4.50	N	3.00	-
6	1.60	4.60	P	3.10	-
7	1.70	4.70	R	3.20	-
8	1.80	4.80	S	3.30	-
9	1.90	4.90	T	3.40	-
A	2.00	5.00	U	3.50	-
B	2.10	-	V	3.60	-
C	2.20	-	X	3.70	-
D	2.30	-	Y	3.80	-
E	2.40	-	Z	3.90	-

③,④ represents production lot number
01～09, 0A～0Z, 11～9Z, A1～A9, AA～AZ, B1～ZZ in order.
(G, I, J, O, Q, W excluded)
*No character inversion used.

■MARKING RULE (Continued)

USPN-4B02



① represents output voltage range

MARK		PRODUCT SERIES
OUTPUT VOLTAGE 1.1V~3.9V	OUTPUT VOLTAGE 4.0V~5.0V	
A	B	XC6504A*****-G

② represents output voltage

MARK	OUTPUT VOLTAGE (V)		MARK	OUTPUT VOLTAGE (V)	
0	-	4.00	F	2.50	-
1	1.10	4.10	H	2.60	-
2	1.20	4.20	K	2.70	-
3	1.30	4.30	L	2.80	-
4	1.40	4.40	M	2.90	-
5	1.50	4.50	N	3.00	-
6	1.60	4.60	P	3.10	-
7	1.70	4.70	R	3.20	-
8	1.80	4.80	S	3.30	-
9	1.90	4.90	T	3.40	-
A	2.00	5.00	U	3.50	-
B	2.10	-	V	3.60	-
C	2.20	-	X	3.70	-
D	2.30	-	Y	3.80	-
E	2.40	-	Z	3.90	-

③ represents production lot number
0～9, A～Z in order.
(G, I, J, O, Q, W excluded)
*No character inversion used.

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